



On 2D Materials & Their Defects under electron irradiation

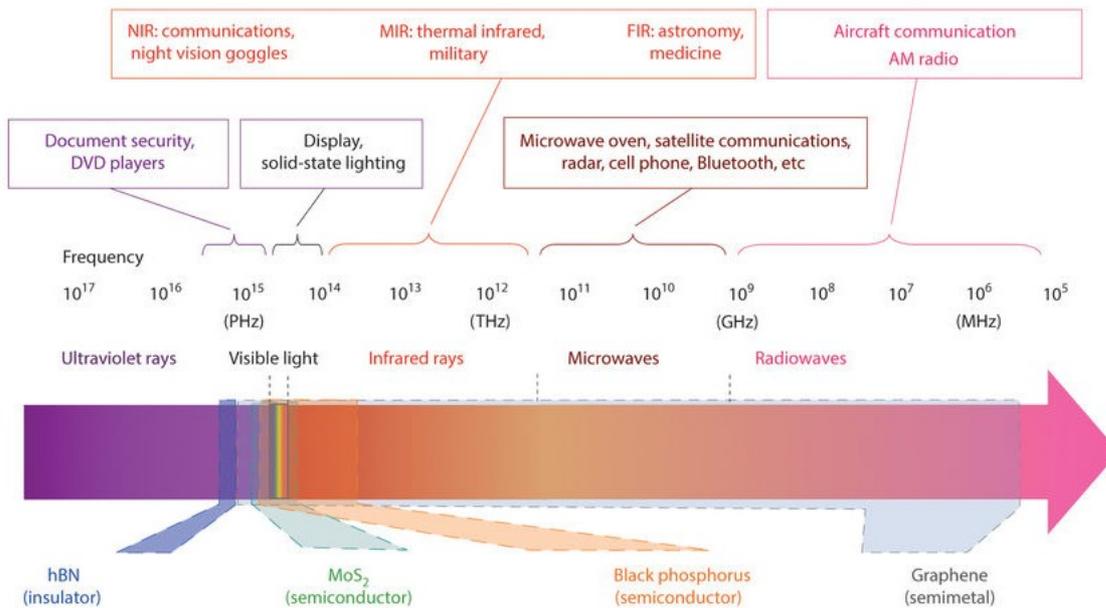
Jani Kotakoski

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<http://dim.univie.ac.at/> jani.kotakoski@univie.ac.at

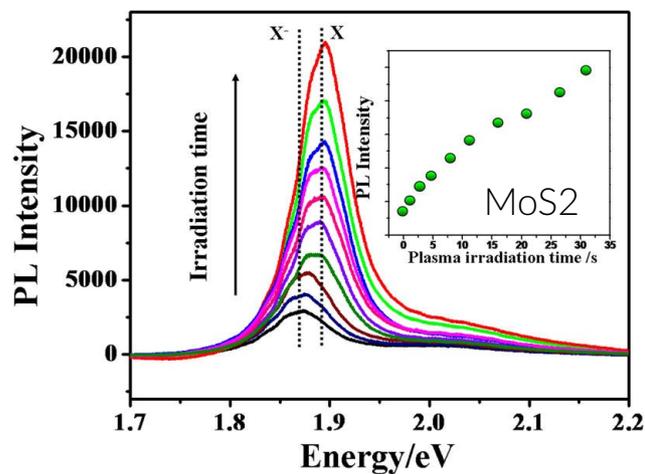
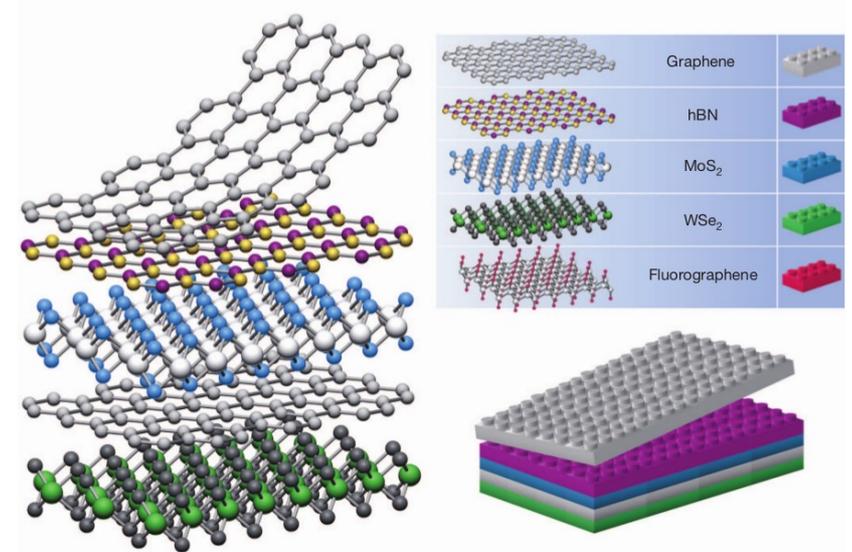
Conference on Physics of Defects in Solids: Quantum Mechanics Meets Topology
9.-13.7.2018 @ ICTP, Trieste, Italy

2D Materials

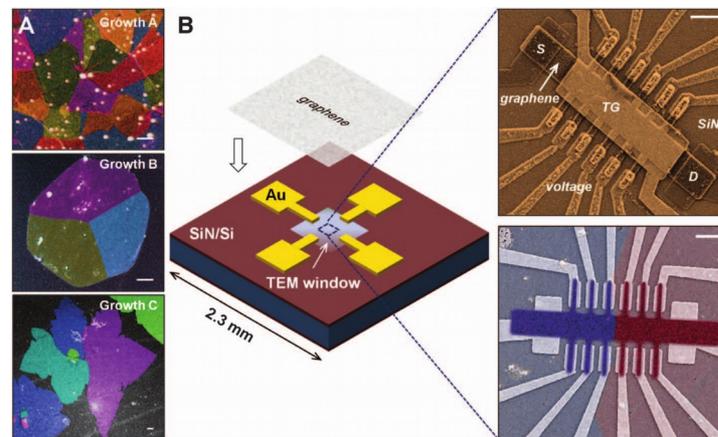
Xia et al., Nat. Photon. 8, 899-907 (2014)



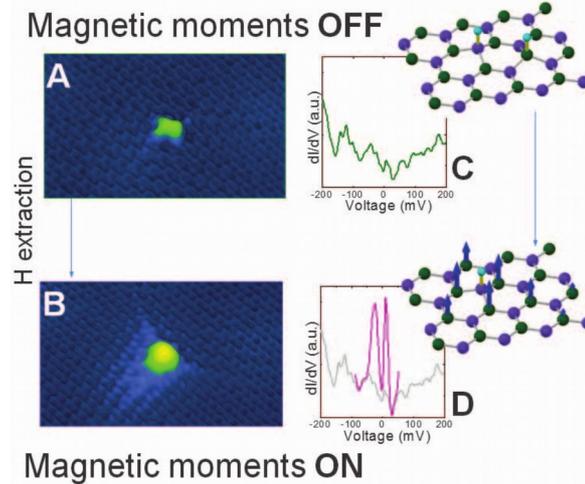
Nature 499, 419 (2013)



Nan et al., ACS Nano 8, 5738 (2014)

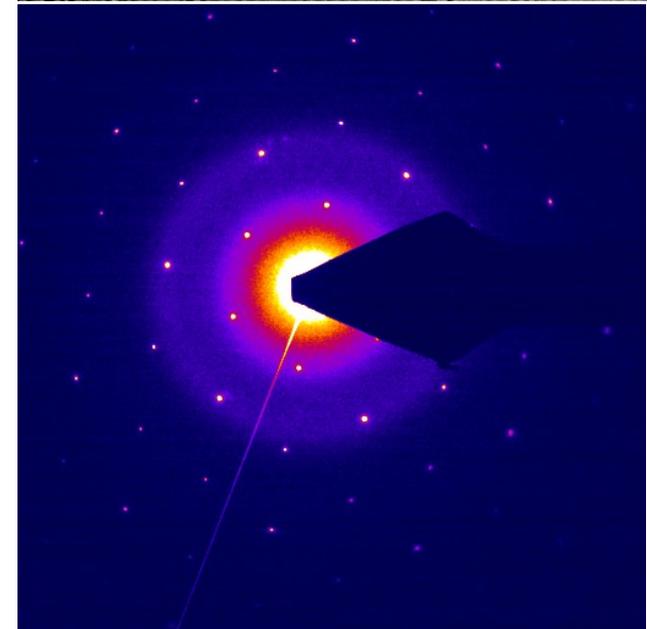
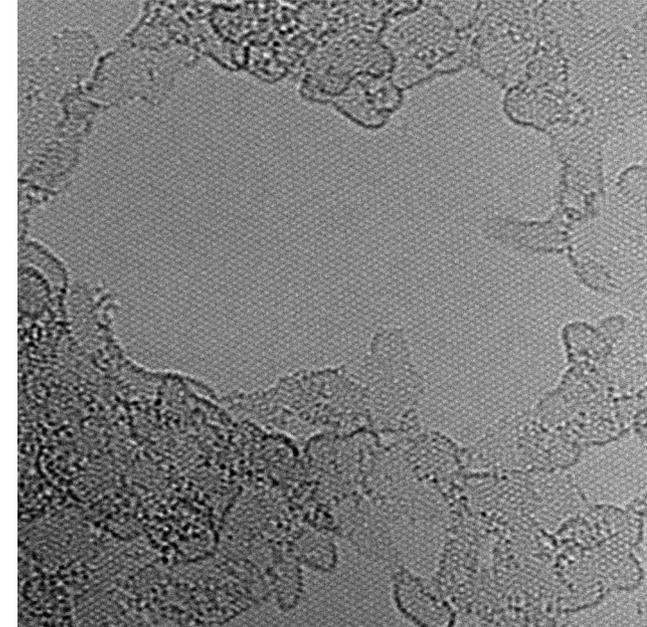
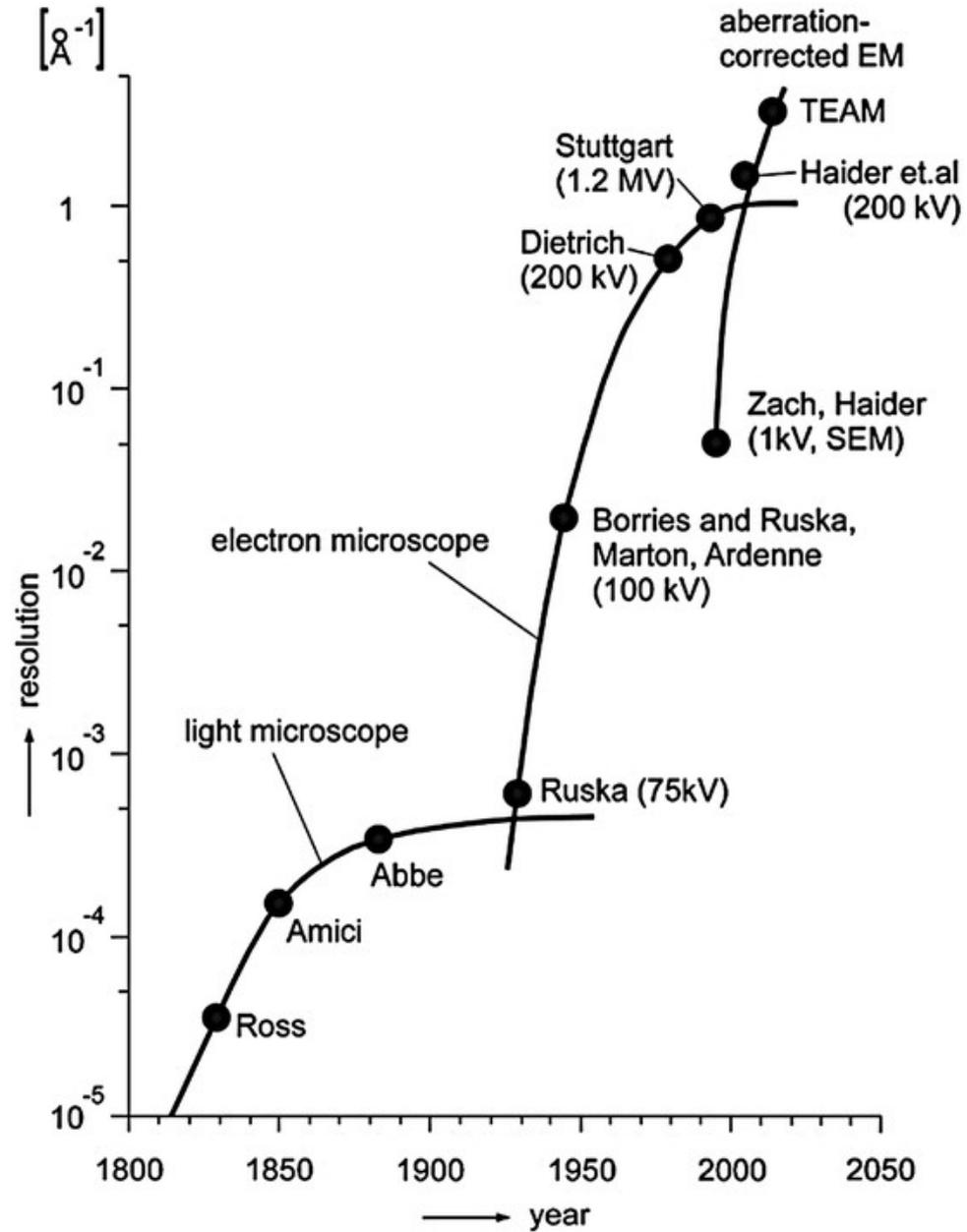


Tsen et al., Science 336, 1143 (2012)



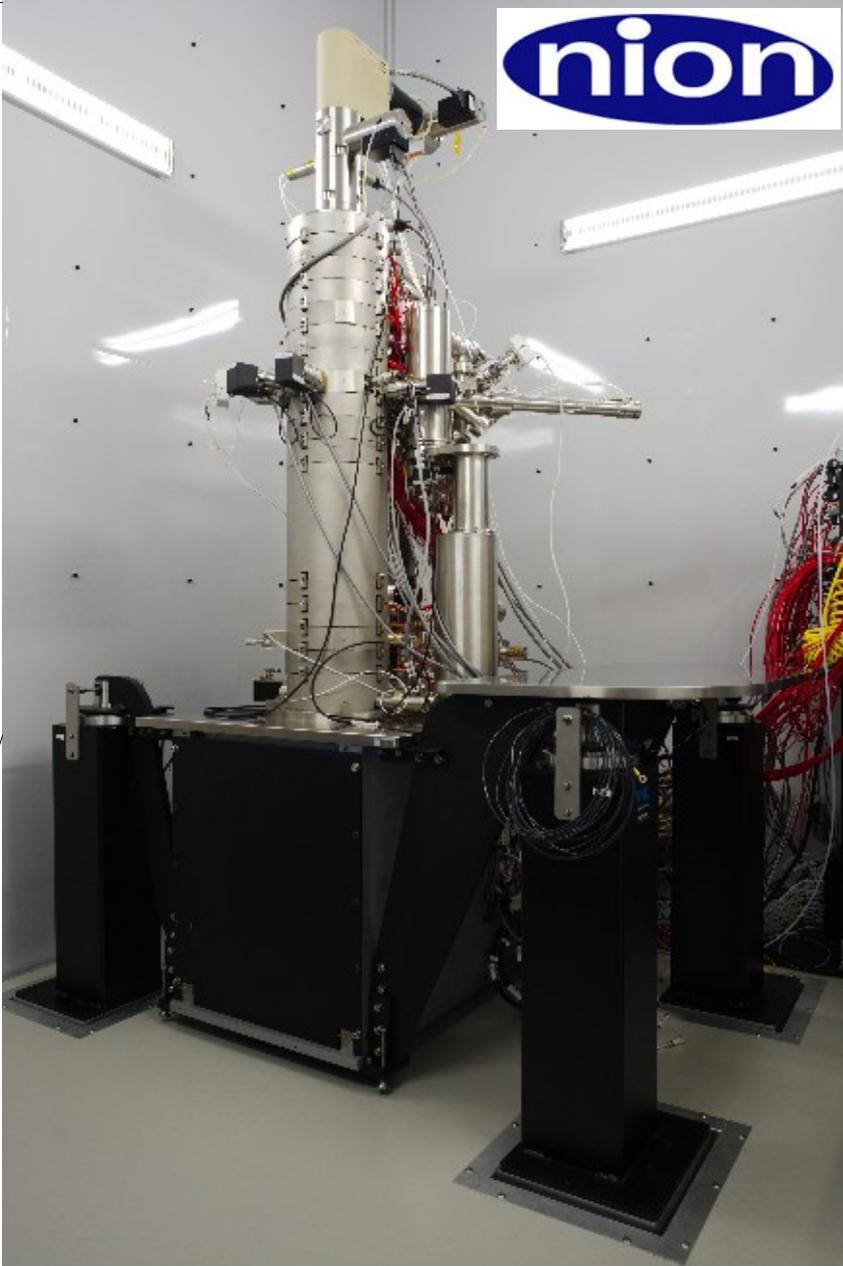
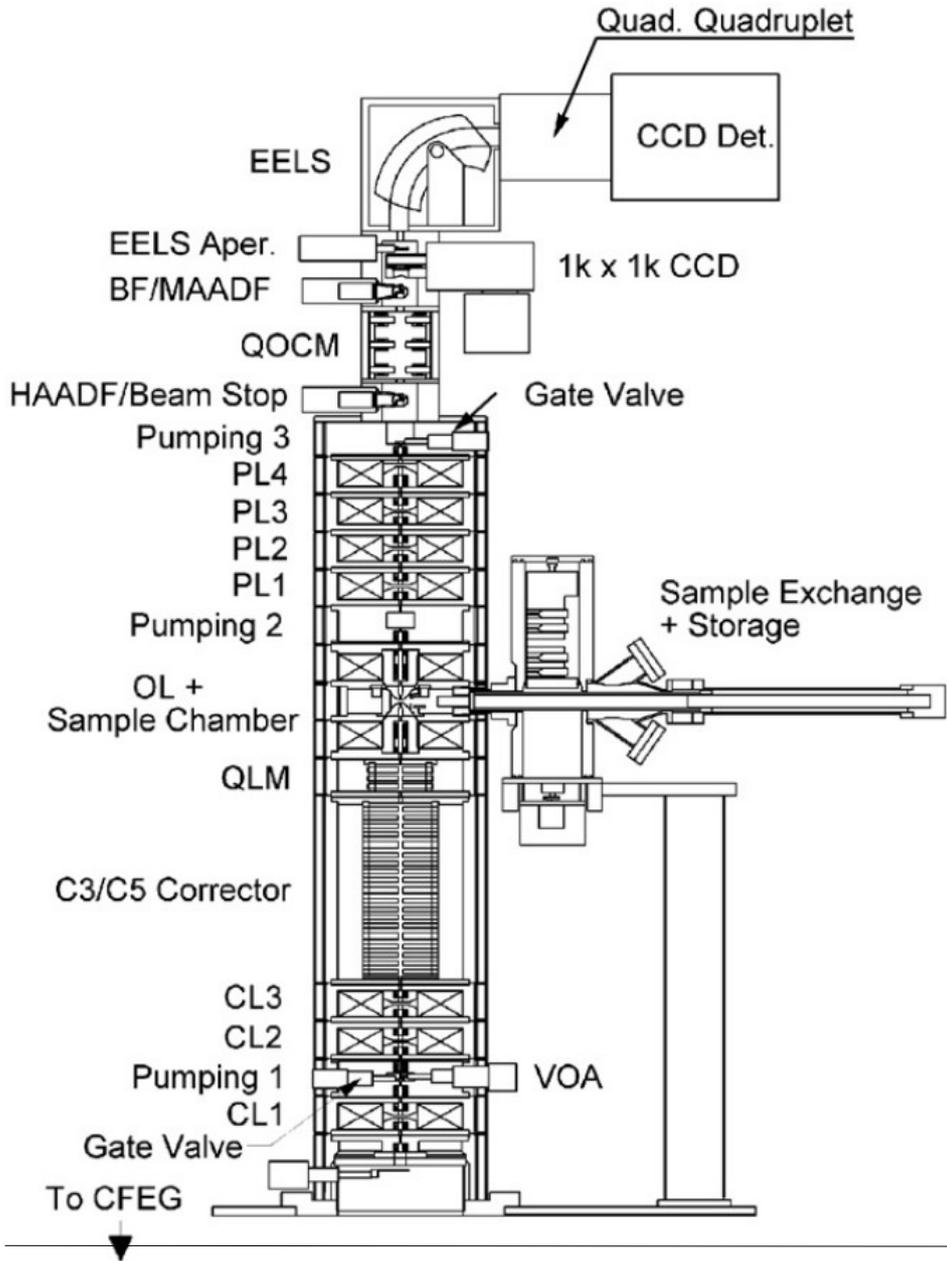
González-Herrero et al., Science 352, 437 (2016)

Transmission Electron Microscopy

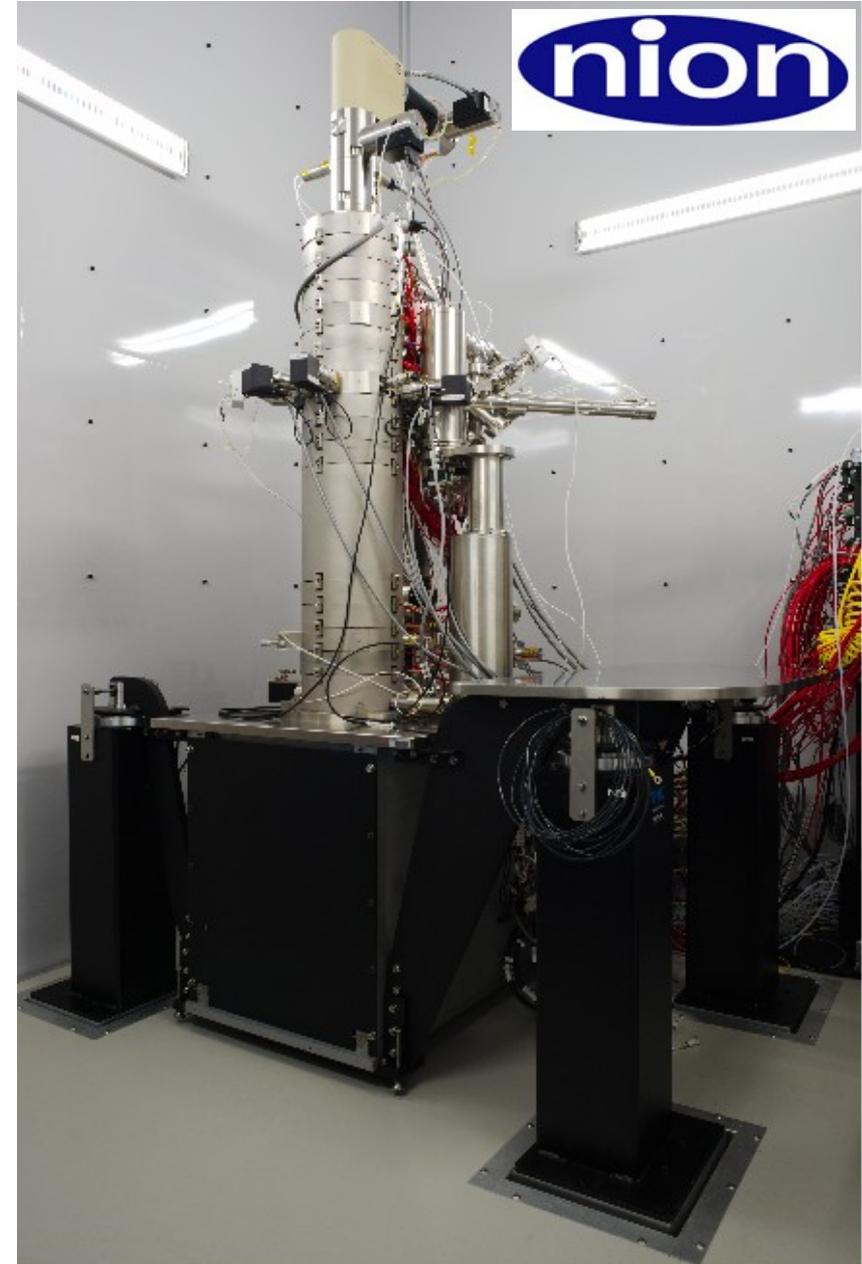
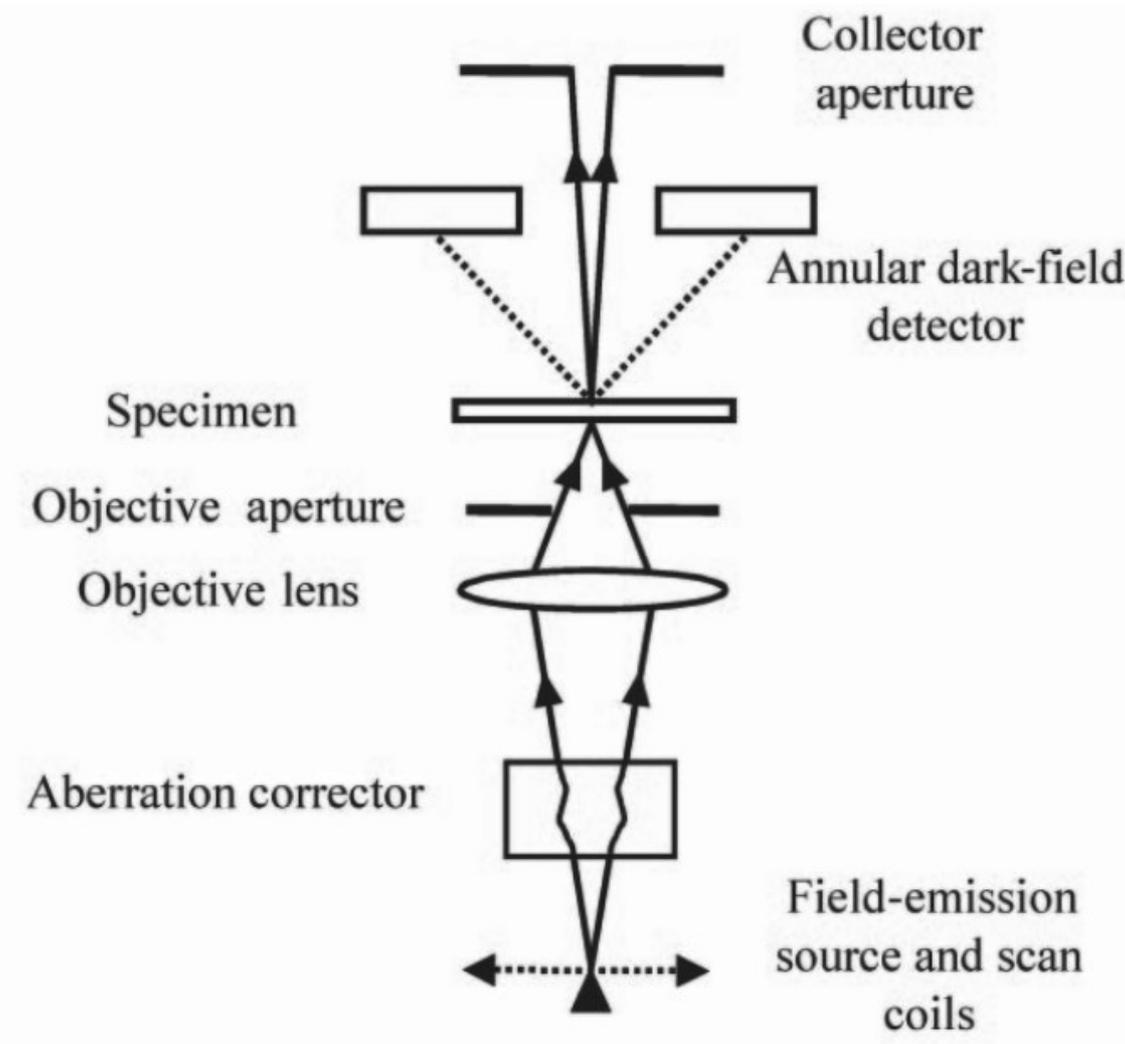


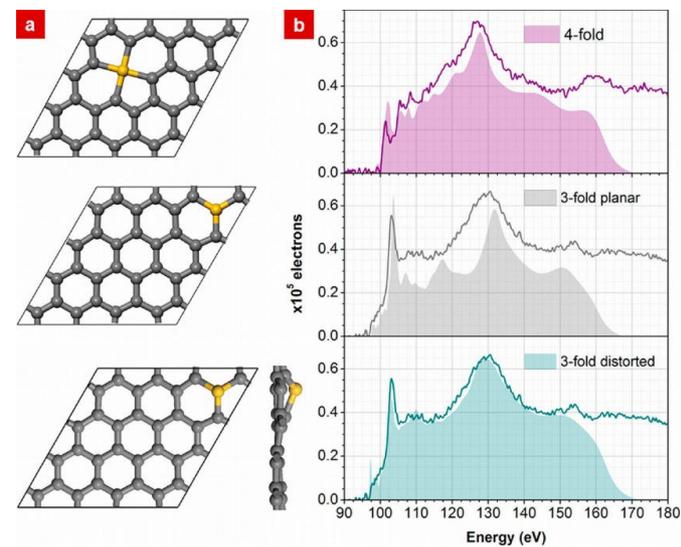
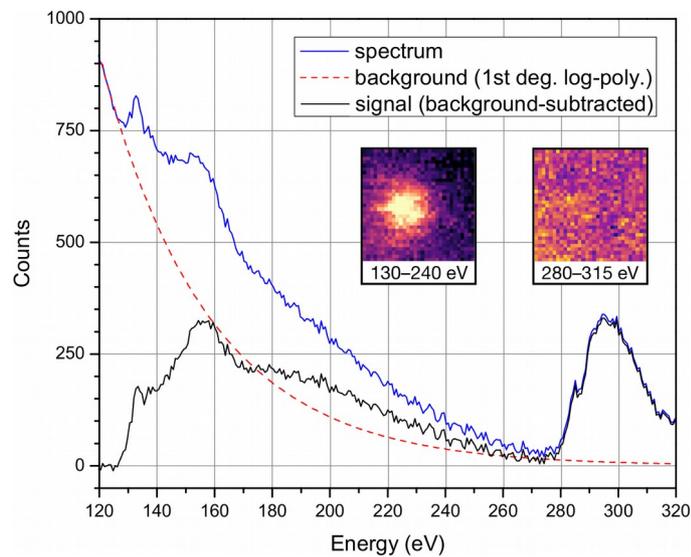
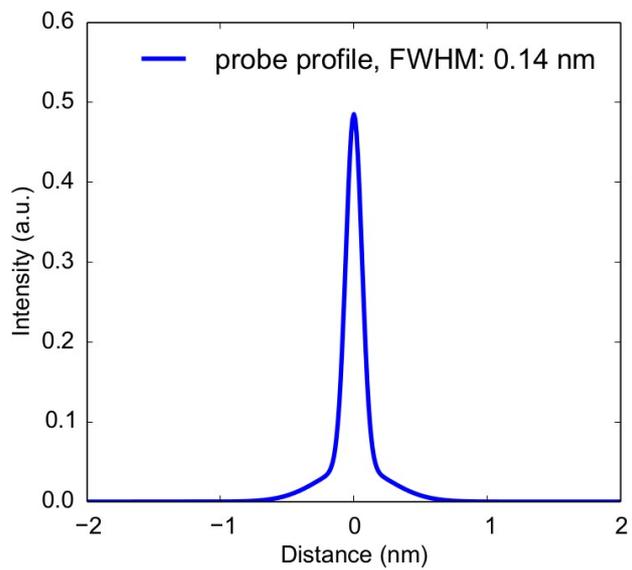
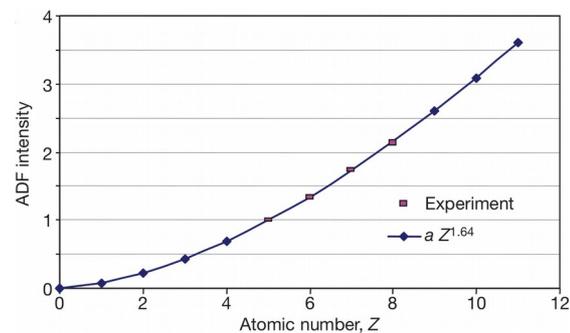
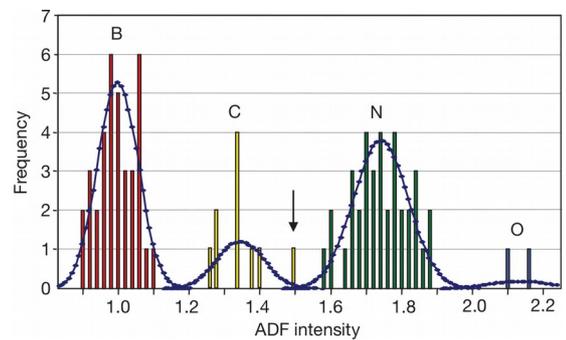
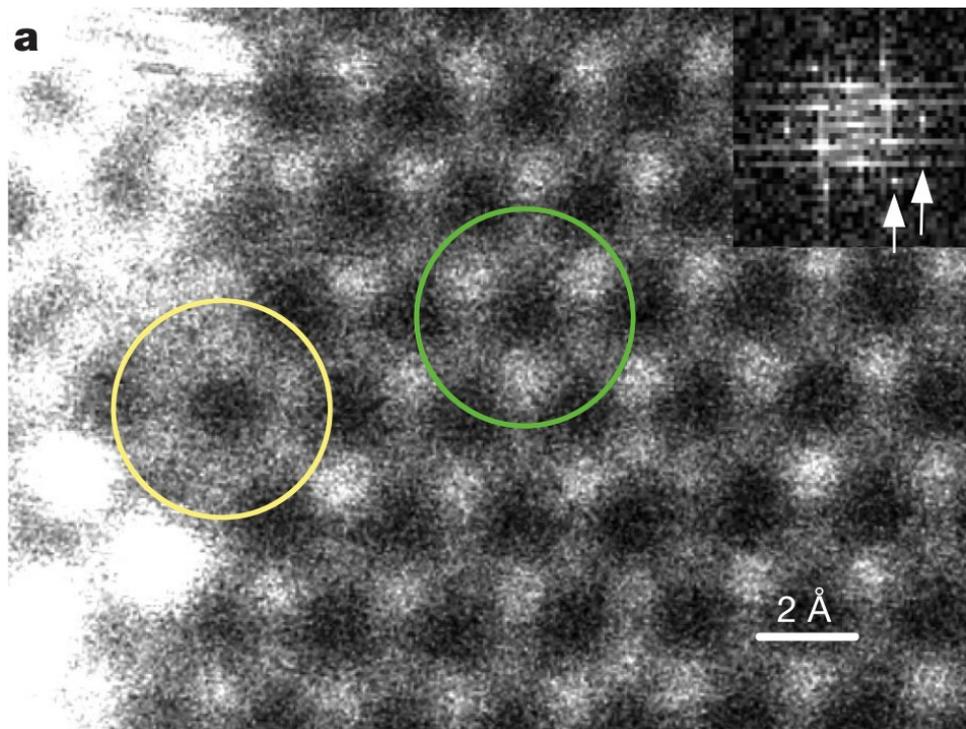
U. Ludacka, FEI Titan 80-300 @ Vienna

Nion UltraSTEM 100 @ Vienna



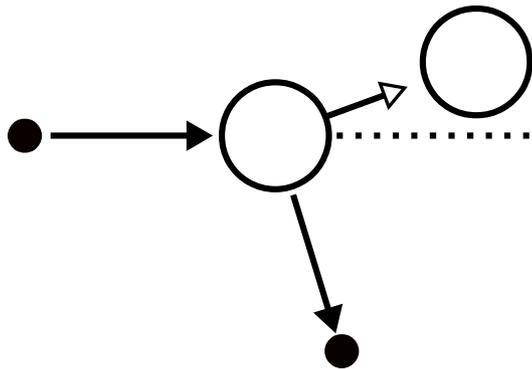
Nion UltraSTEM 100 @ Vienna



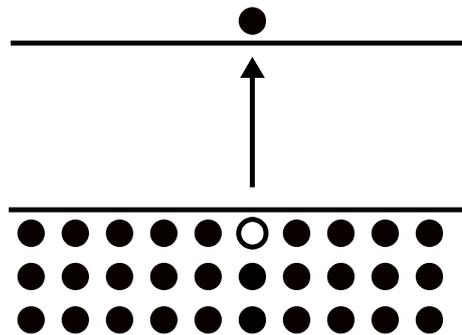


Electron Beam Effects in the (S)TEM

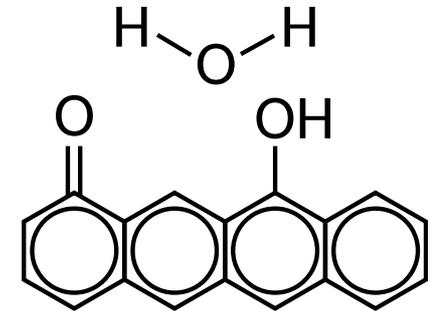
knock-on



excitations & ionization



chemical effects



Characteristic cross sections and time scales for carbon @ 100 kV

Knock-on dynamics

cross section: < 1 barn
time scale: 10^{-15} s

Phonons (elastic collision)

cross section: 10^6 barn
time scale: 10^{-12} s

Ionization

cross section: 10^6 barn
time scale: 10^{-15} s

Core hole

cross section: 10^4 barn
time scale: 10^{-14} s

Plasmons

cross section: 10^6 barn
time scale: 10^{-13} s

Beam Current: 30 pA
ca. $1 \text{ e}^- / \text{nm}^2 / 10^{-9} \text{ s}$

Knock-On Process

Banhart, Rep. Prog. Phys. 62, 1181 (1999)

Conservation of energy

$$E_e^{\text{tot}} + E_n^{\text{tot}} = \tilde{E}_e^{\text{tot}} + \tilde{E}_n^{\text{tot}}$$

Conservation of momentum

$$\vec{p}_e + \vec{p}_n = \vec{\tilde{p}}_e + \vec{\tilde{p}}_n$$

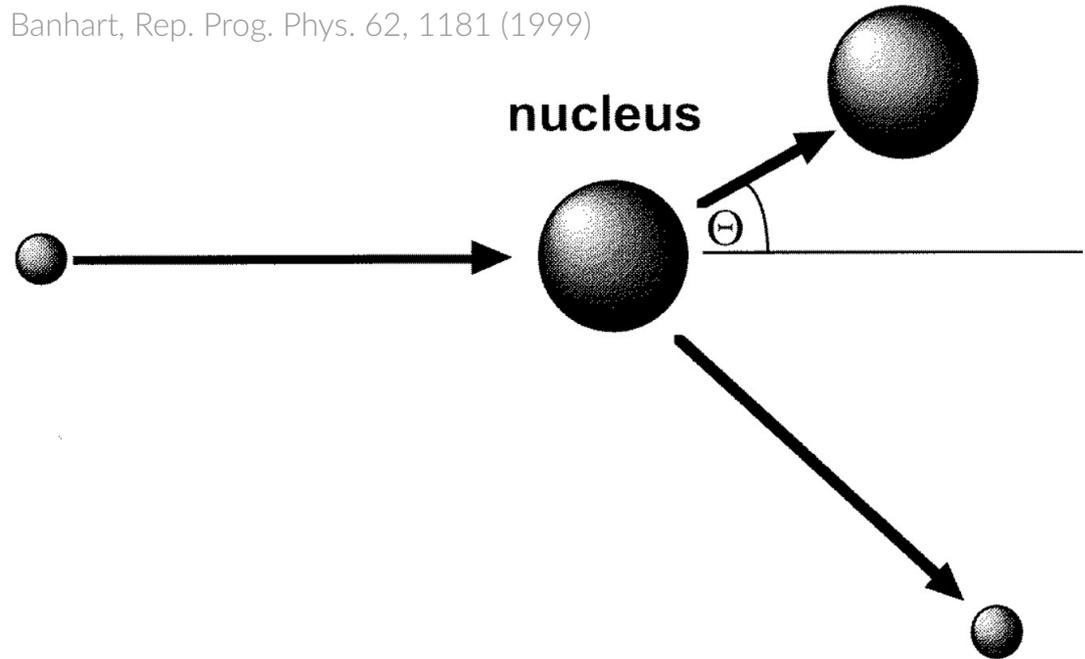


Figure 1. Geometry of scattering of a light particle (electron) by a nucleus.

Maximum energy transfer occurs for the back scattering electron and yields

$$E_{\text{max}}(E_e, v) = \frac{\left(2\sqrt{E_e(E_e + 2mc^2)} + M(vc)\right)^2}{2Mc^2}$$

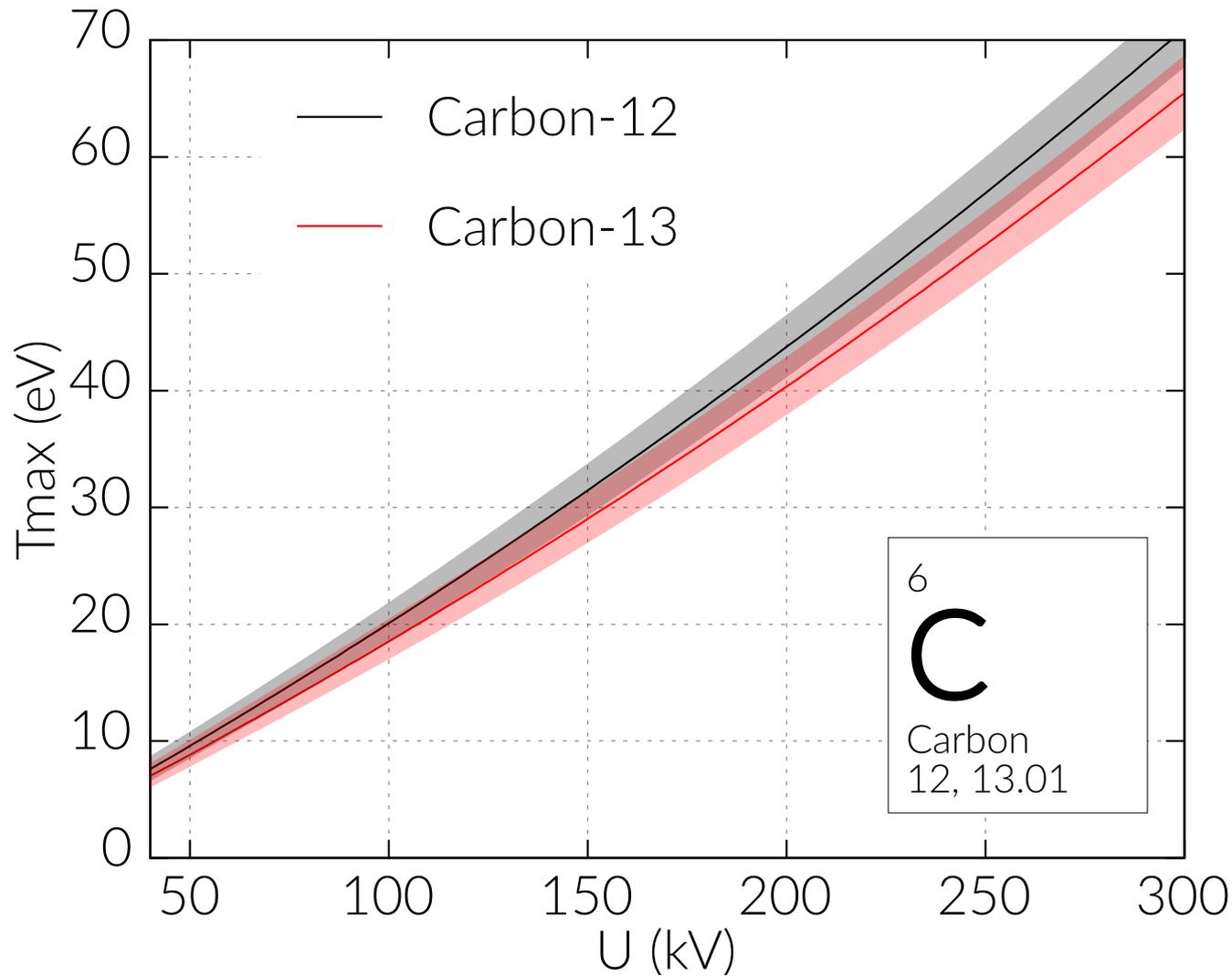
Electron energy: eU

Initial velocity of the nucleus

$$\text{or } E_{\text{max}}(E_e) = \frac{2E_e(E_e + 2m_e c^2)}{Mc^2} \quad \text{for } v = 0$$

$$E_{\max}(E_e, v) = \frac{\left(2\sqrt{E_e(E_e + 2mc^2)} + Mv\right)^2}{2Mc^2}$$

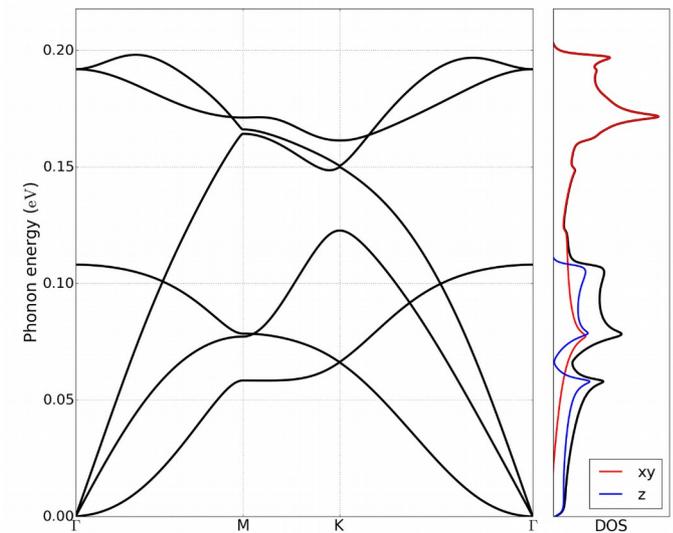
m : 0.51 MeV/c²
 M : $Z \times 931.49$ MeV/c²



Velocity here from kinetic theory:

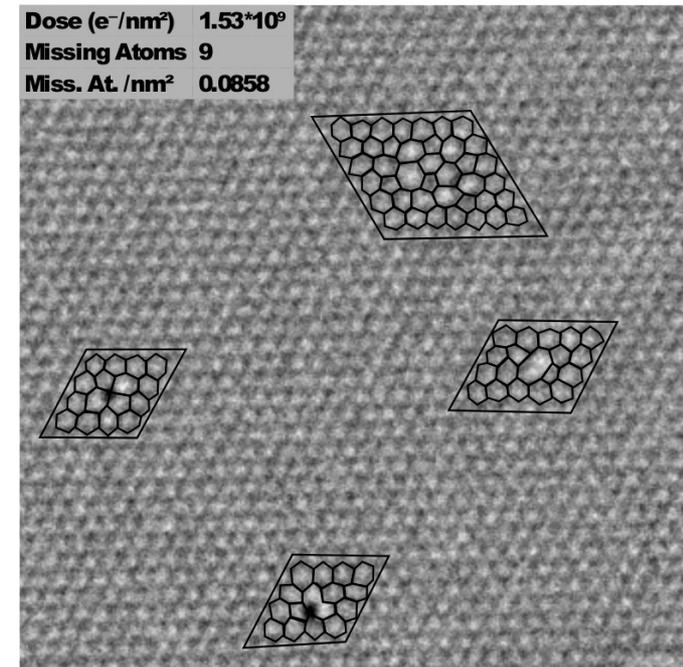
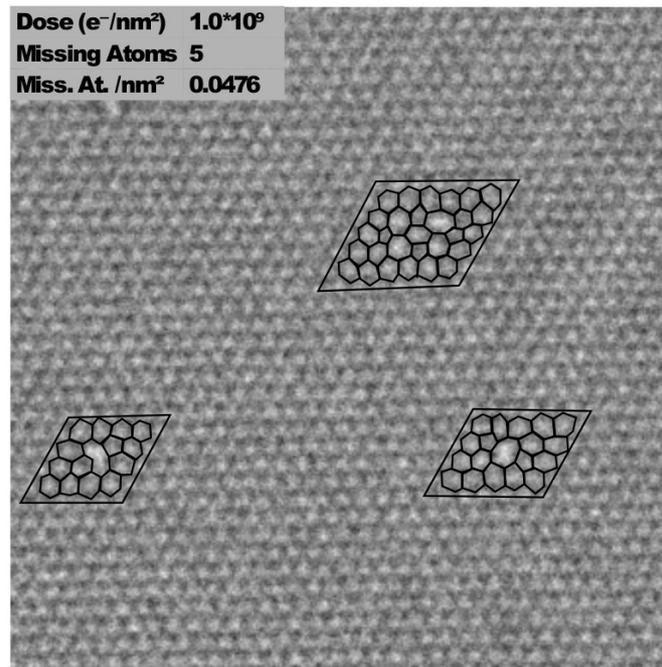
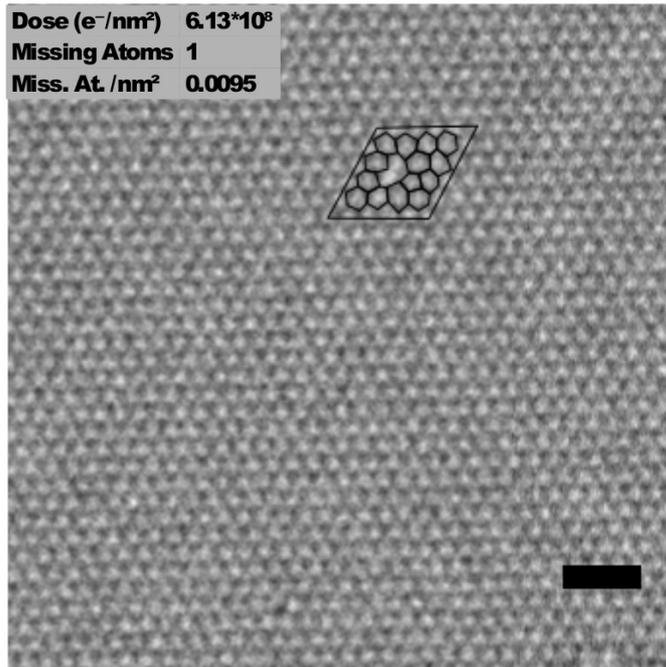
$$k_B T = \frac{m\overline{v^2}}{3}$$

Better, phonon DOS:



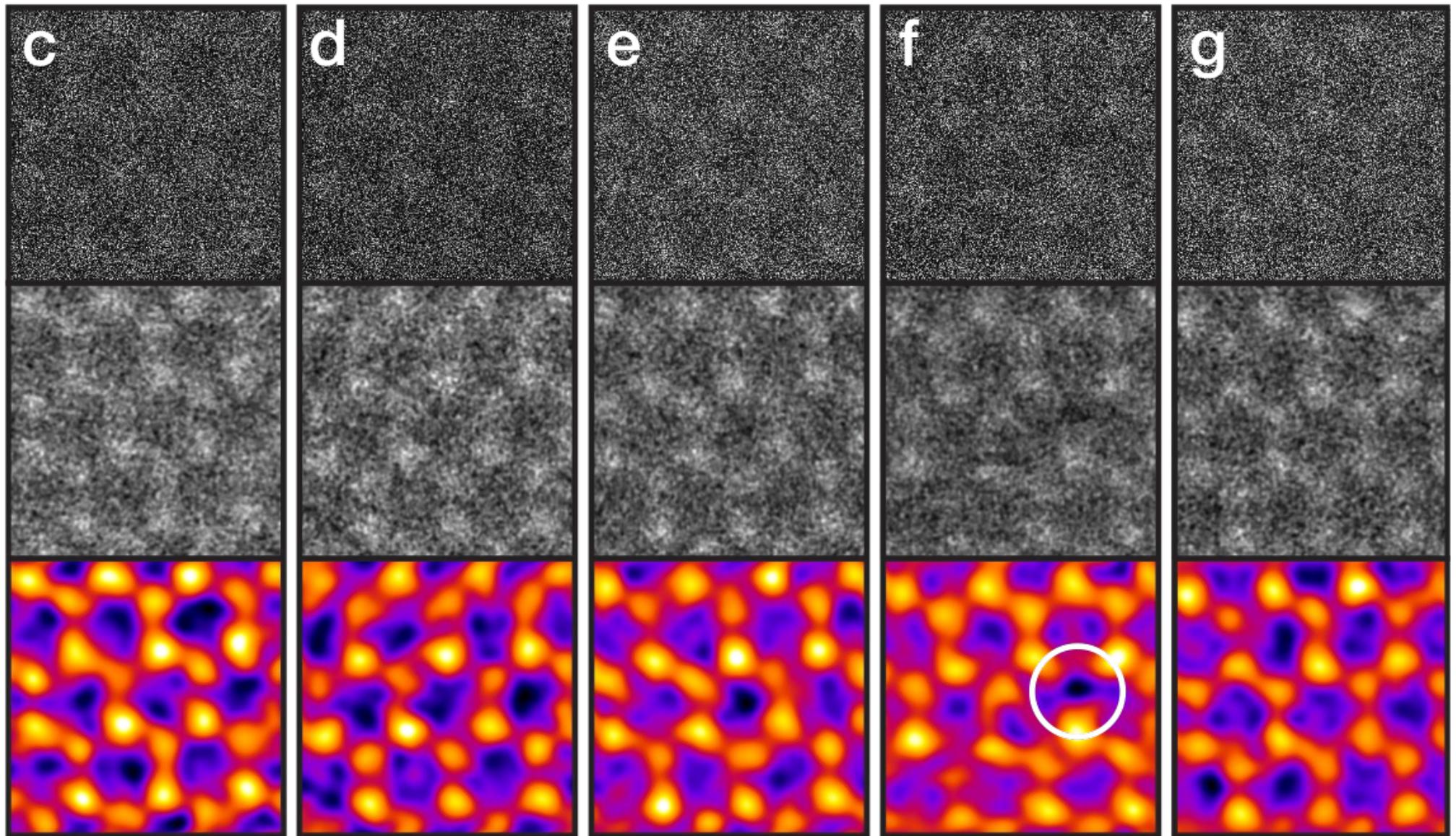
$$\overline{v_z^2}(T) = U_z / (2M) = \frac{\hbar}{2M} \int_0^{\omega_z} g_z(\omega) \left[\frac{1}{2} + \frac{1}{\exp(\hbar\omega / (kT)) - 1} \right] \omega d\omega$$

Graphene @ 90 kV, TEM



Meyer, JK et al., Phys. Rev. Lett. (2012)

Graphene @ 95 kV, STEM



Displacement Cross Section

Coulomb Interaction: $V(\mathbf{r}) = \frac{-e^2 Q_1 Q_2}{4\pi\epsilon_0 r}$ Nucleus: $Q_2 = Z$
 Electron: $Q_1 = 1$

Rutherford scattering: $\frac{d\sigma}{d\Omega} = \left(\frac{Z_1 Z_2 \alpha(\hbar c)}{4E_K \sin^2 \frac{\theta}{2}} \right)^2$ (valid for charges at low energies)

Extended for spin and relativistic electrons by Mott & approximated by McKinley and Feshbach:

$$\sigma(\theta) = \sigma_R \left[1 - \beta^2 \sin^2(\theta/2) + \pi \frac{Ze^2}{\hbar c} \beta \sin(\theta/2) (1 - \sin(\theta/2)) \right]$$

Electron scattering angle

Using

$$T(\theta) = T_{max} \sin^2(\theta/2)$$

one gets

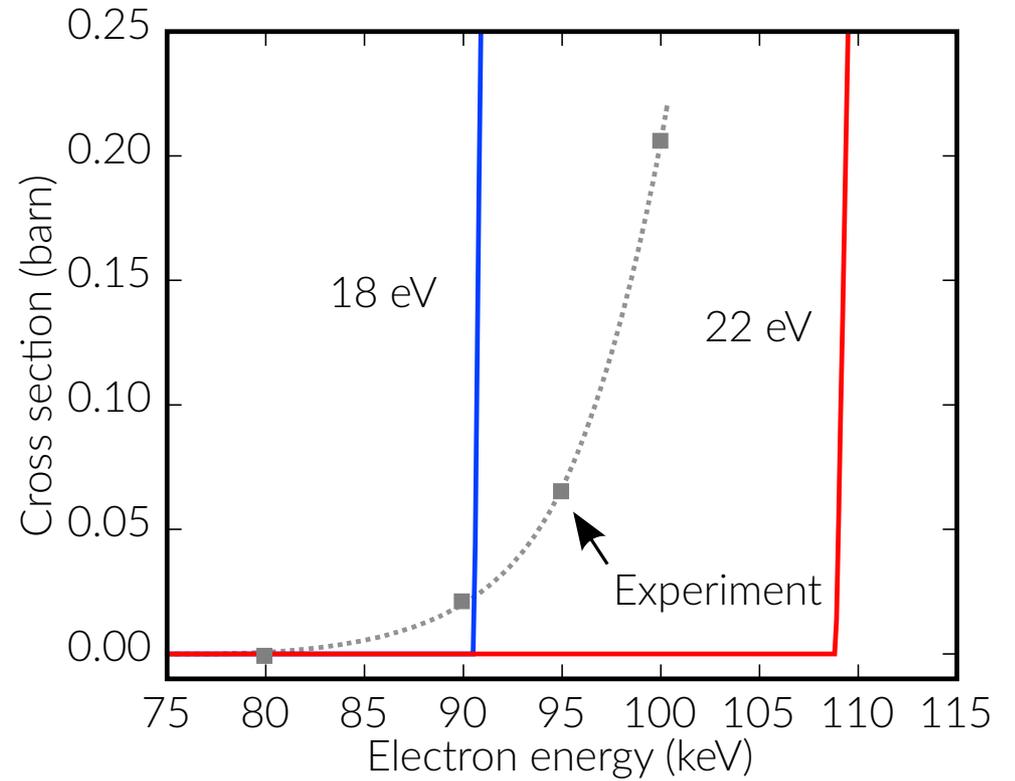
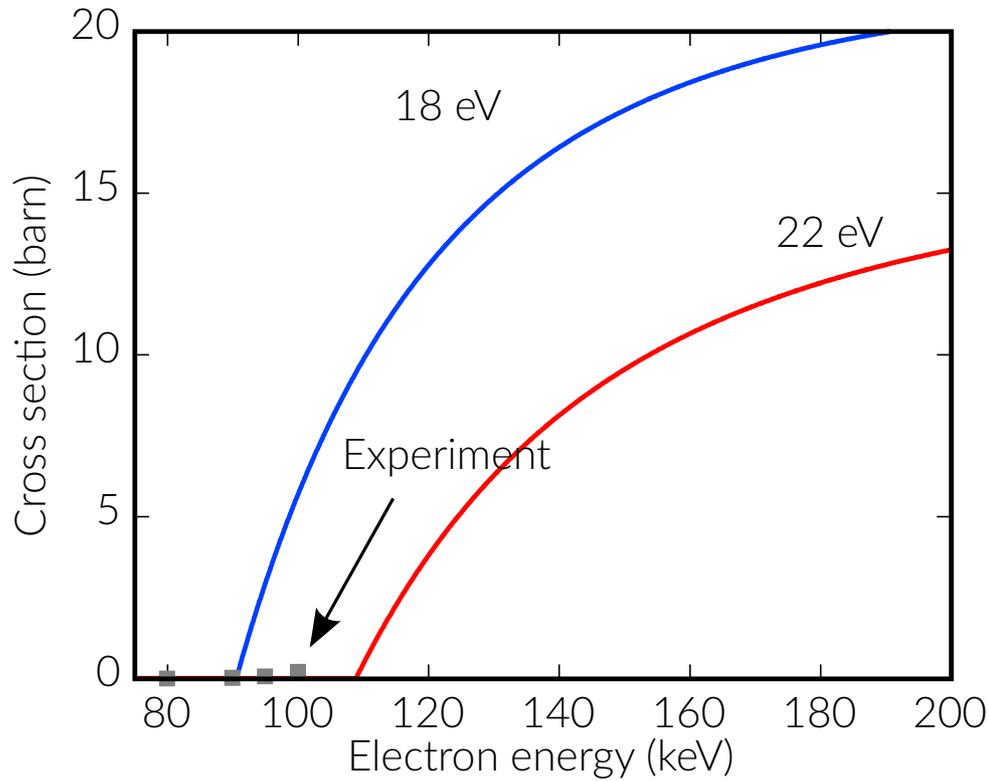
$$\sigma(T) = \left(\frac{Ze^2}{4\pi\epsilon_0 2m_0 c^2} \frac{T_{max}}{T} \right)^2 \frac{1 - \beta^2}{\beta^4} \left[1 - \beta^2 \frac{T}{T_{max}} + \pi \frac{Ze^2}{\hbar c} \beta \left(\sqrt{\frac{T}{T_{max}}} - \frac{T}{T_{max}} \right) \right]$$

Energy of nucleus after scattering

Assuming isotropic displacement threshold E_d and integrating over $T > E_d$ leads to:

$$\sigma_d = 4\pi \left(\frac{Ze^2}{4\pi\epsilon_0 2m_0 c^2} \right)^2 \frac{1 - \beta^2}{\beta^4} \left\{ \frac{T_m}{E_d} - 1 - \beta^2 \ln \left(\frac{T_m}{E_d} \right) + \pi \frac{Ze^2}{\hbar c} \beta \left[2 \left(\frac{T_m}{E_d} \right)^{1/2} - \ln \left(\frac{T_m}{E_d} \right) - 2 \right] \right\}$$

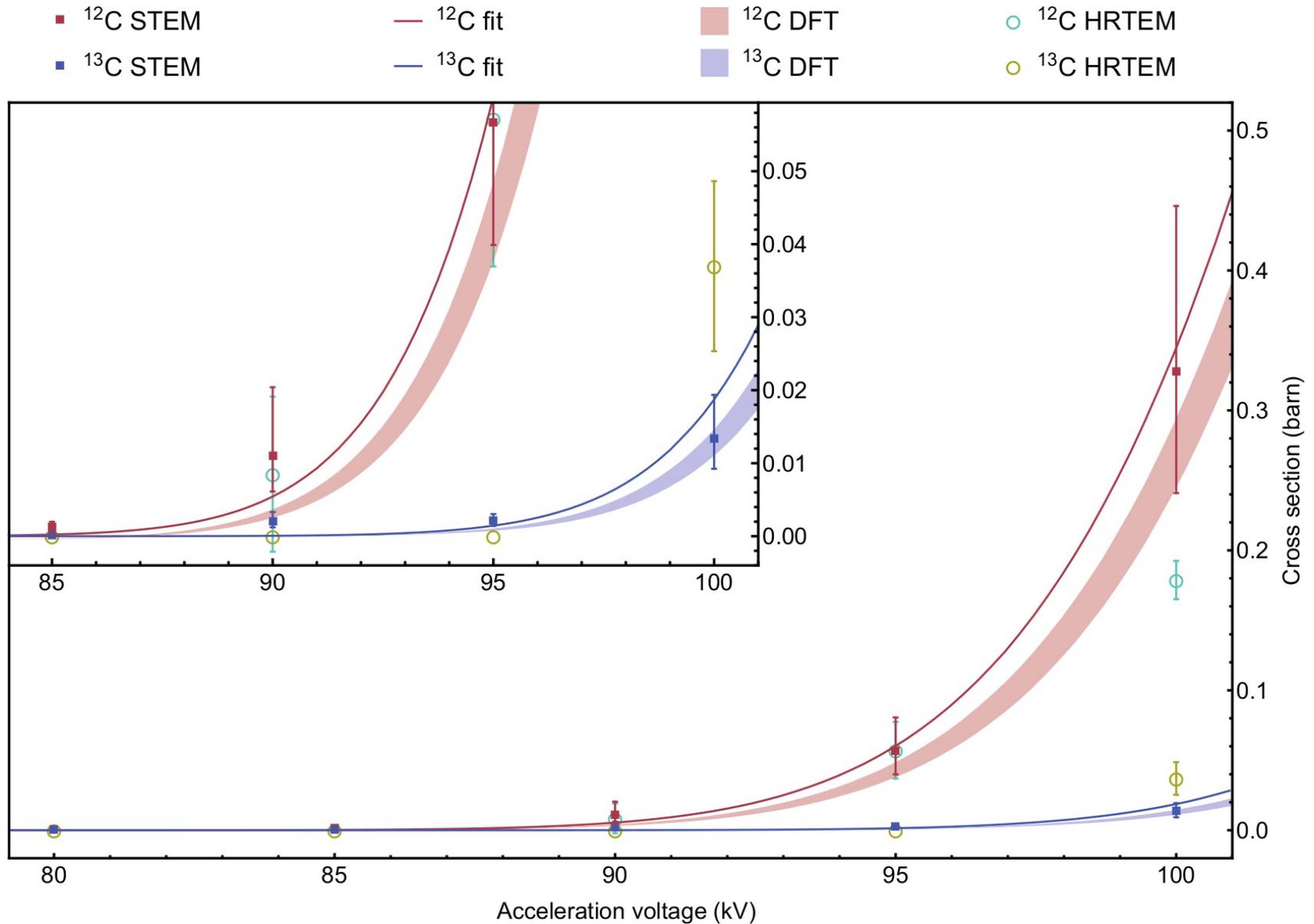
Theory vs. experiment



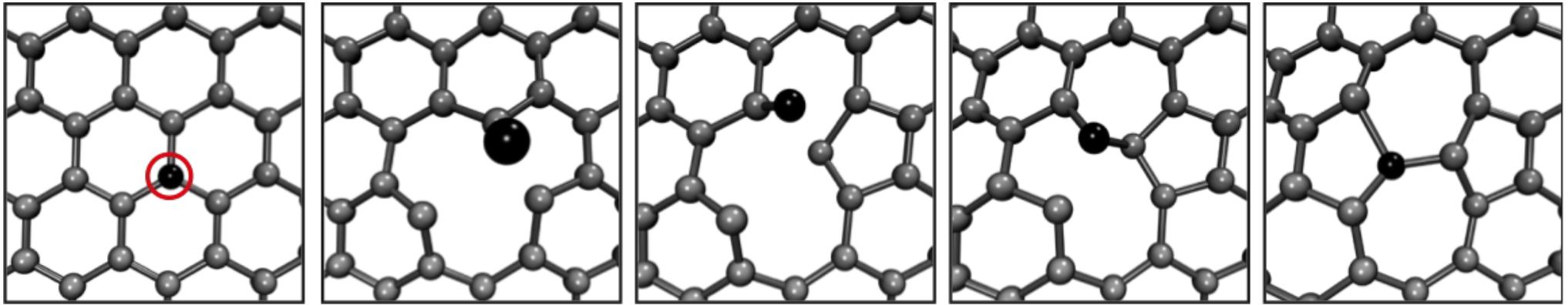
$$\sigma_d = 4\pi \left(\frac{Ze^2}{4\pi\epsilon_0 2m_0c^2} \right)^2 \frac{1-\beta^2}{\beta^4} \left\{ \frac{T_m}{E_d} - 1 - \beta^2 \ln\left(\frac{T_m}{E_d}\right) + \pi \frac{Ze^2}{\hbar c} \beta \left[2\left(\frac{T_m}{E_d}\right)^{1/2} - \ln\left(\frac{T_m}{E_d}\right) - 2 \right] \right\}$$

Extended model:
$$\sigma(T, E_e) = \int_{E_{max}(v, E_e) \geq T_d} P(v, T) \sigma(E_{max}(v, E_e)) dv$$

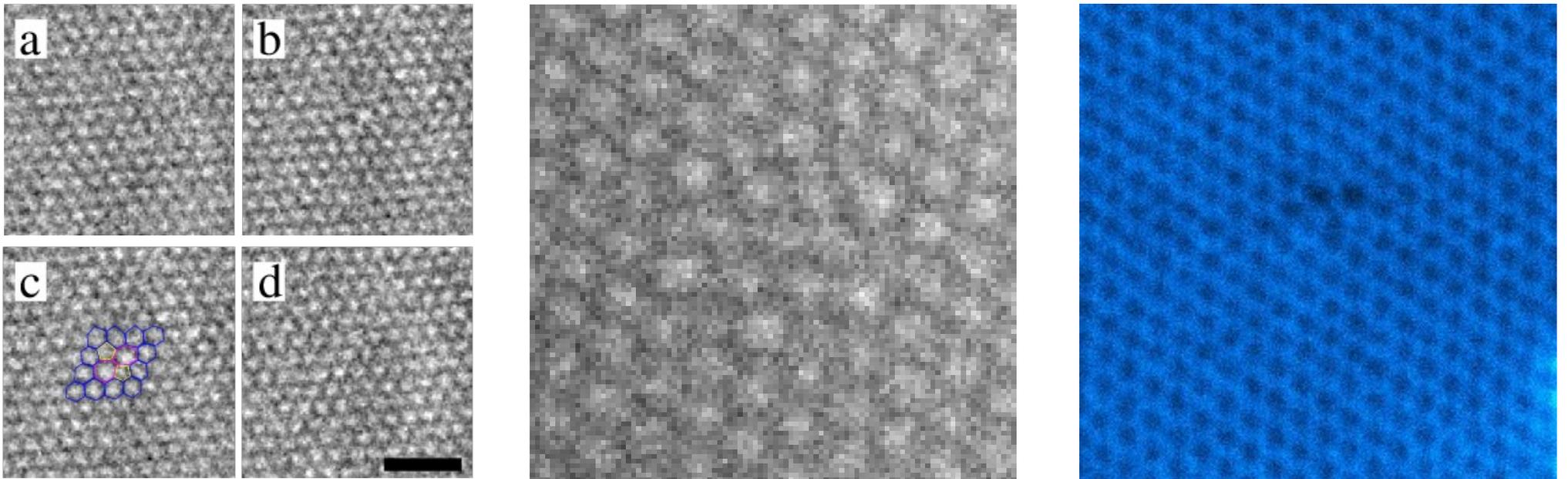
Velocity distribution of nuclei



Sub-threshold Knock-On Effects



Dynamical process due to an impact on one atom



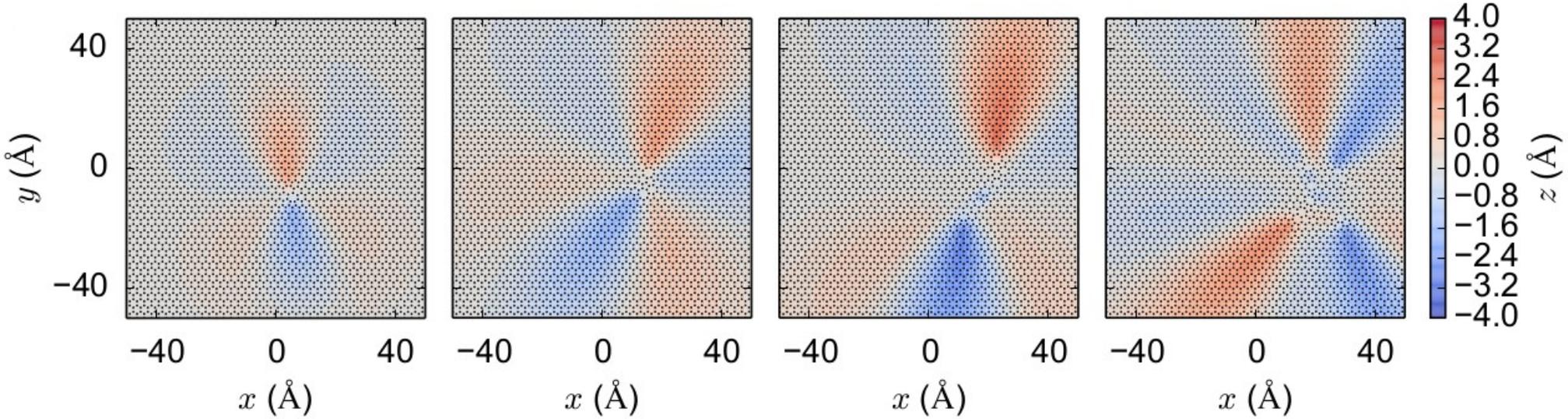
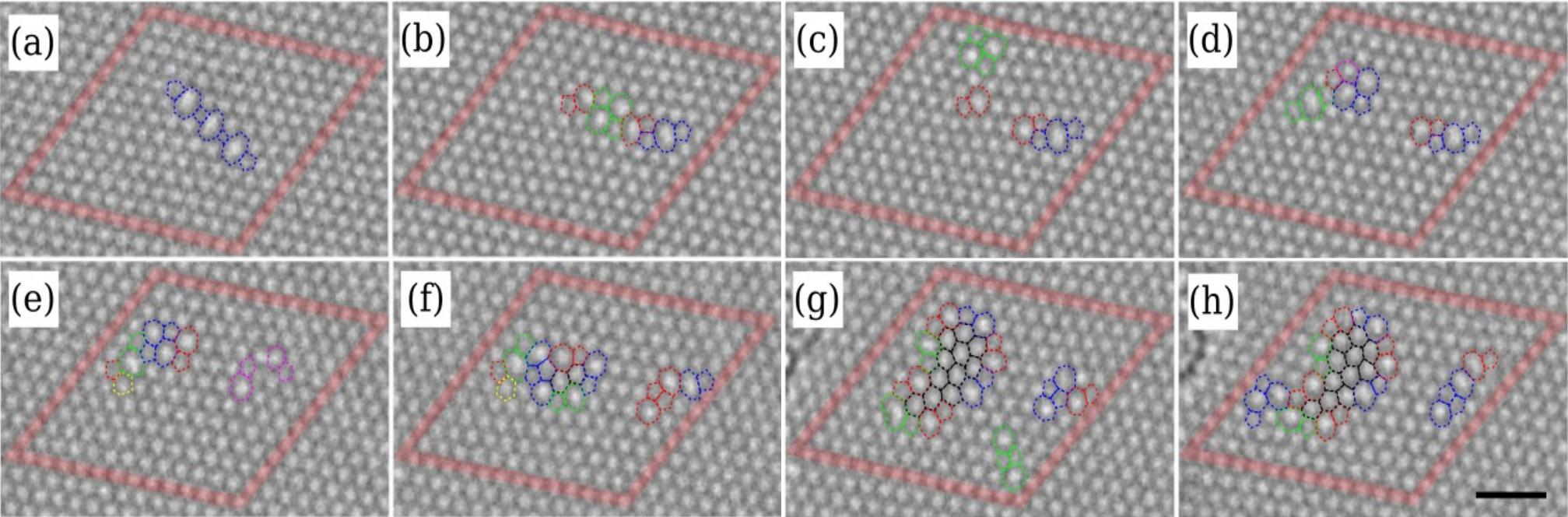
Stone-Wales

„Flower defect“

Divacancy

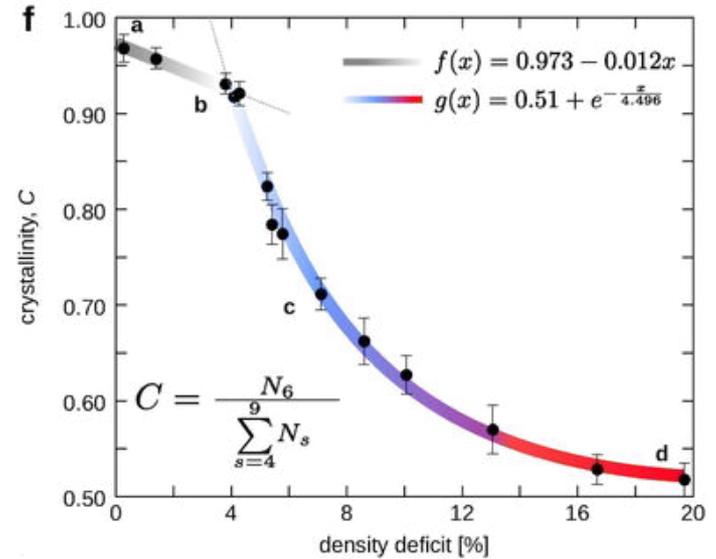
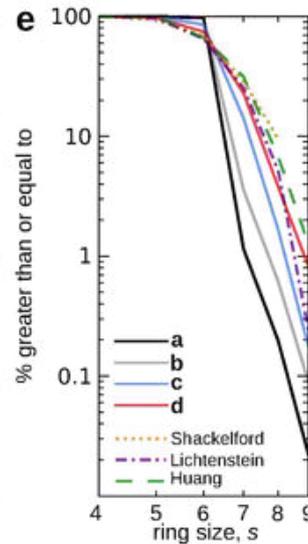
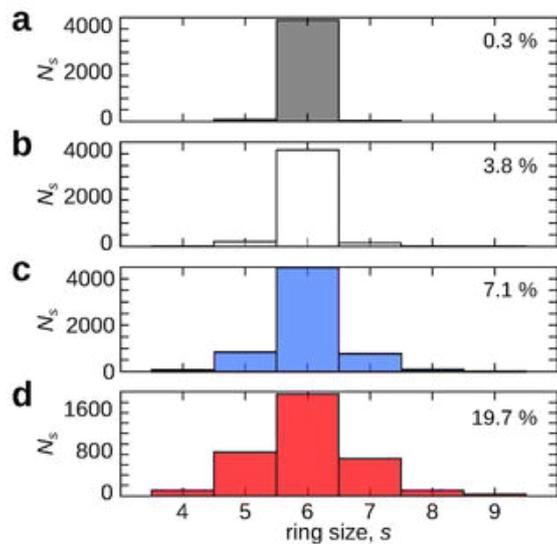
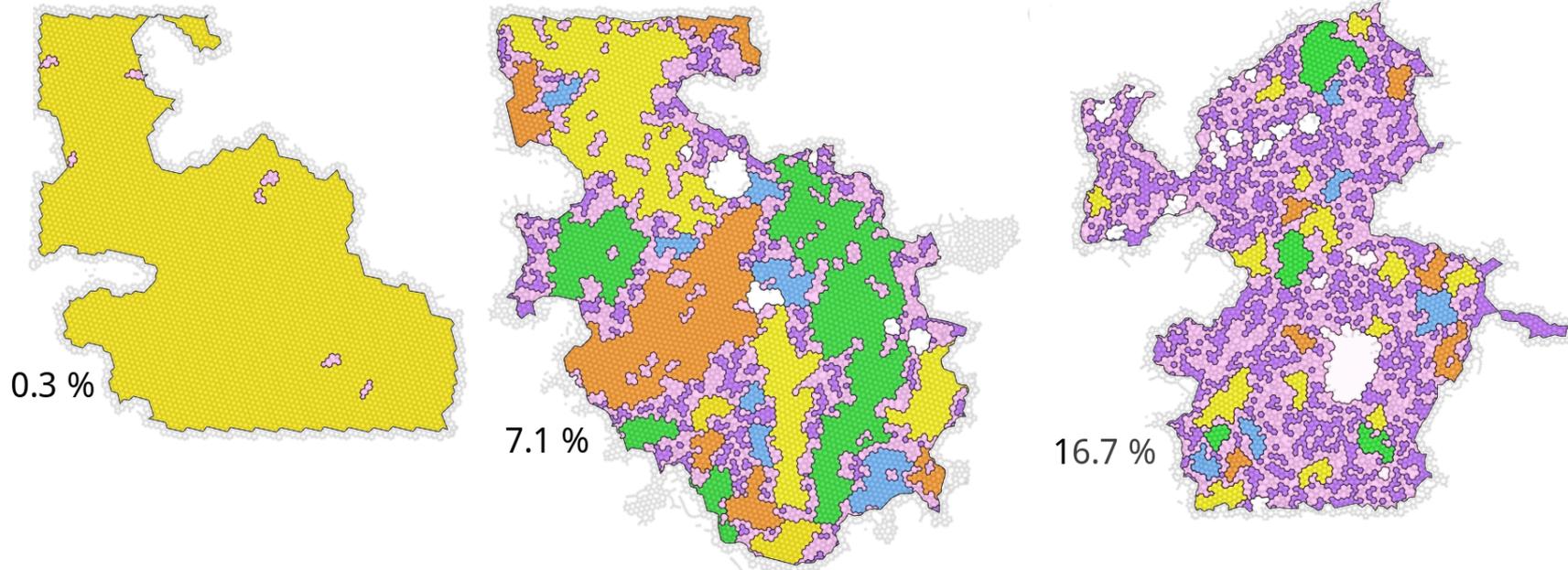
From Single- to Multivacancies

@ 100 kV



... and to Amorphous 2D Carbon

@ 100 kV

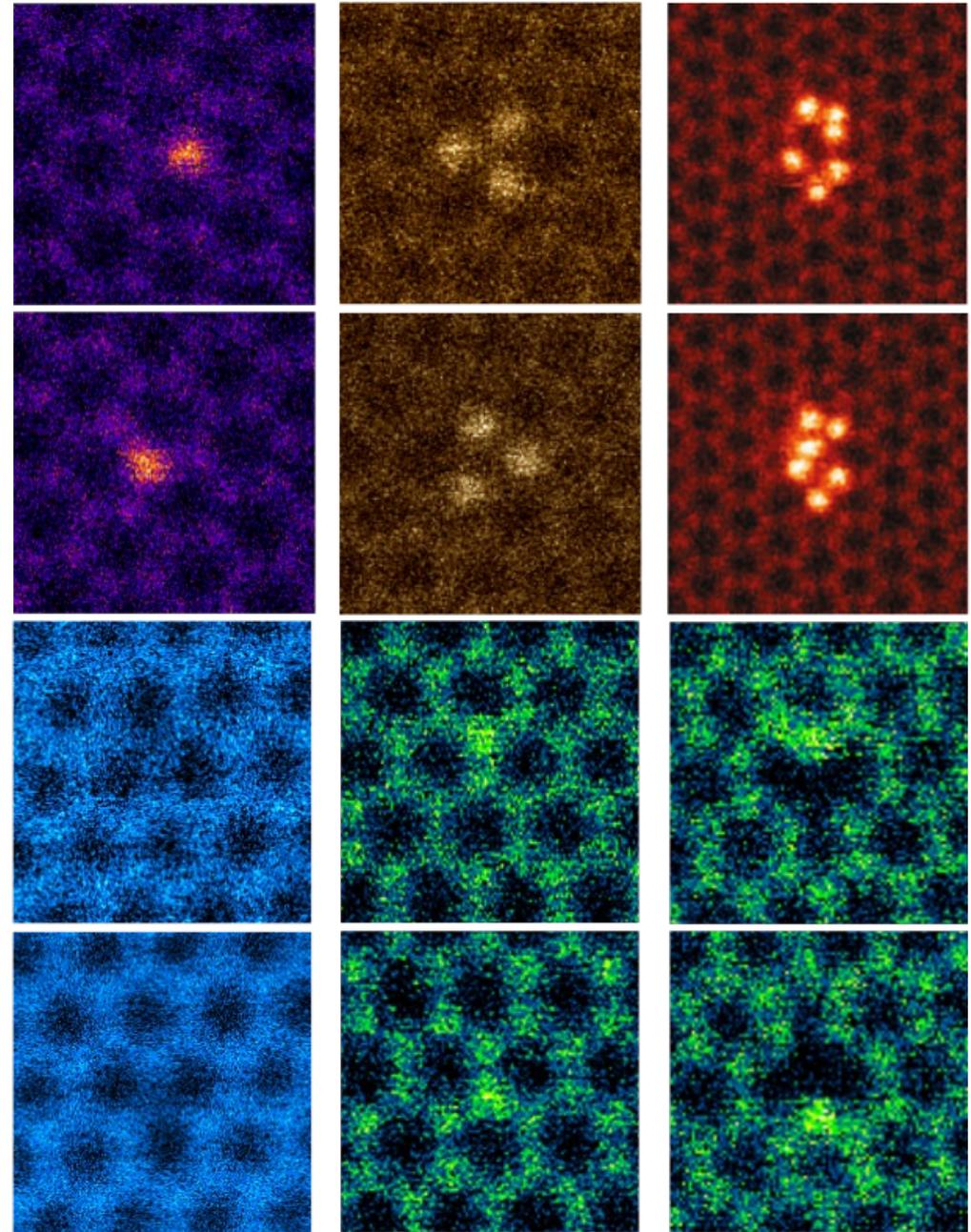


Impurity Atom Dynamics

Observed dynamics

Atom	Event	T_d^{exp}	T_d^{sim}
^{12}C	KO	21.14	21.9
^{13}C	KO	21.14	21.9
N_{sub}	KO	>20.4	19.1
$\text{C}@N_{\text{sub}}$	KO	17.5	19.2
$\text{C}@N_{\text{sub}}$	Jump	15.9	—
$\text{C}@N_{\text{pyr}}$	Jump	9.7	—
B	KO	15.9	18
$\text{C}@B$	KO	15.1	19.6
$\text{C}@B$	Jump	14.8	18.5
Si	KO	>10.0	13.3
$\text{C}@Si$	KO	12.8	16.9
$\text{C}@Si$	Jump	13.0	14.8

Susi, ..., JK, 2D Mater. 4, 042004 (2017)

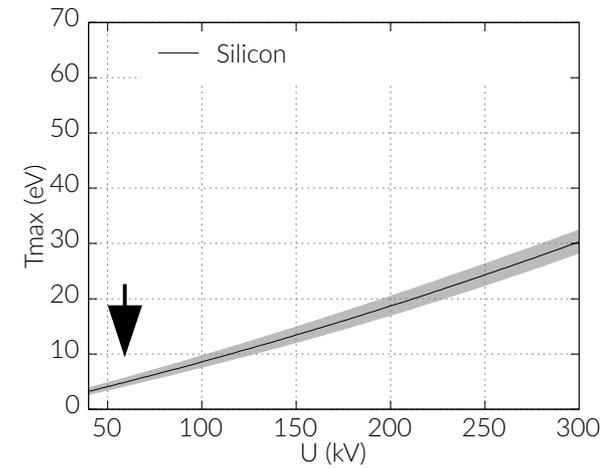
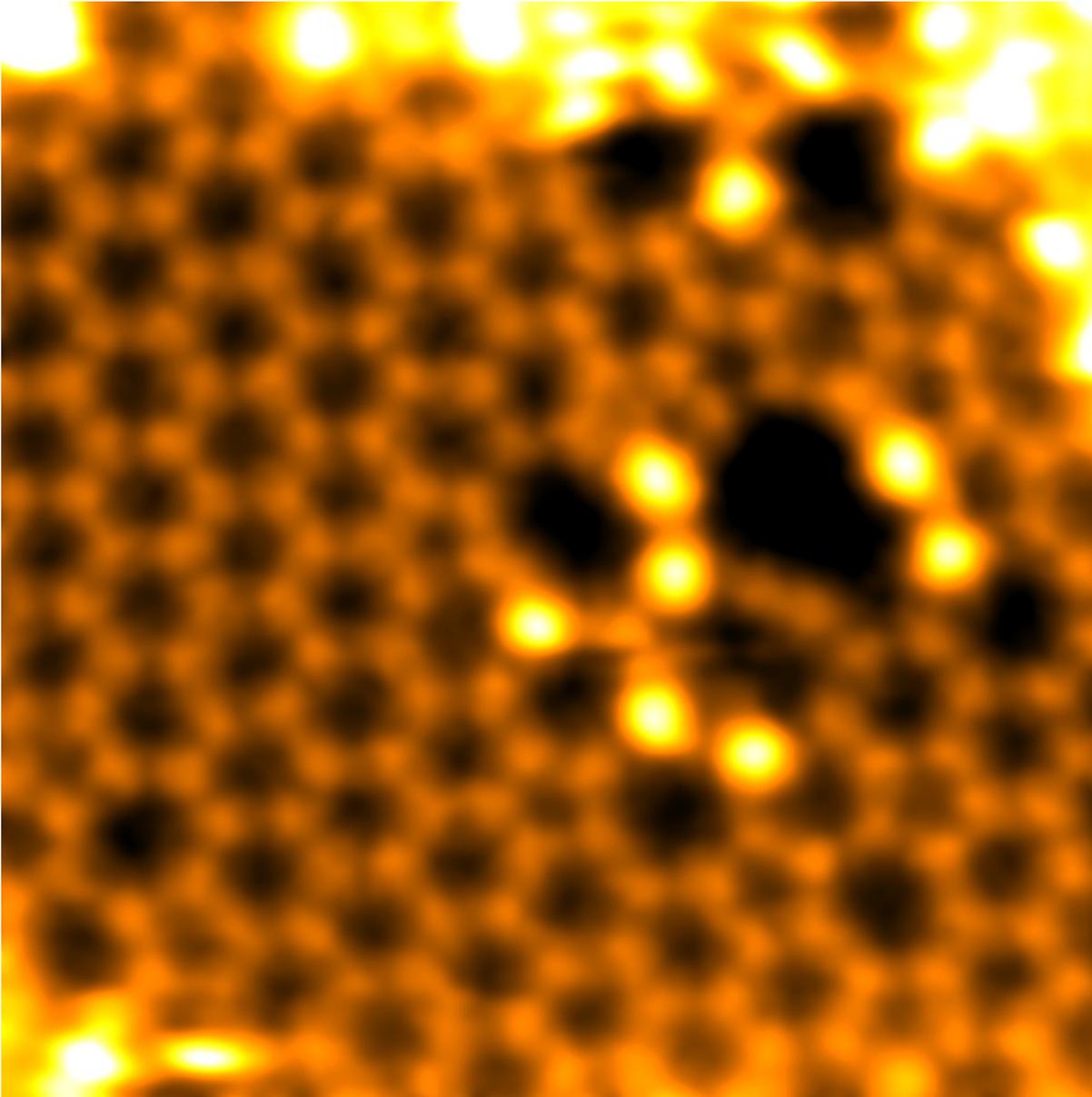


Susi, JK, et al. Phys. Rev. Lett. 113, 115501 (2014),
 Yang et al., Angewandte Chemie 126, 9054 (2014),
 Lee et al., Nature 4, 1650 (2013), Lin et al., Nano Letters 15, 74087413
 (2015), Kepaptsoglou et al., ACS Nano 9, 11398 (2015)

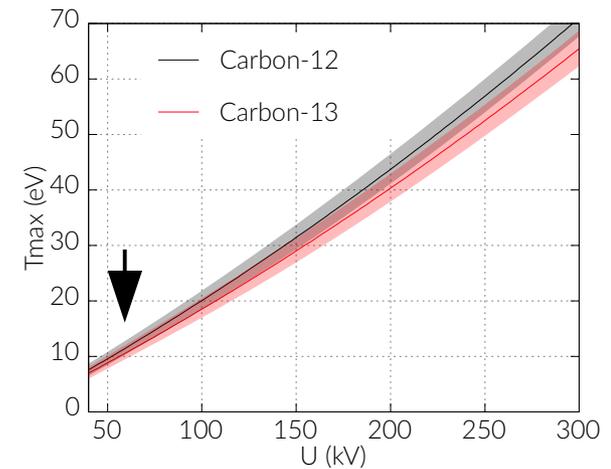
Hints Towards 2D Silicon Carbide?

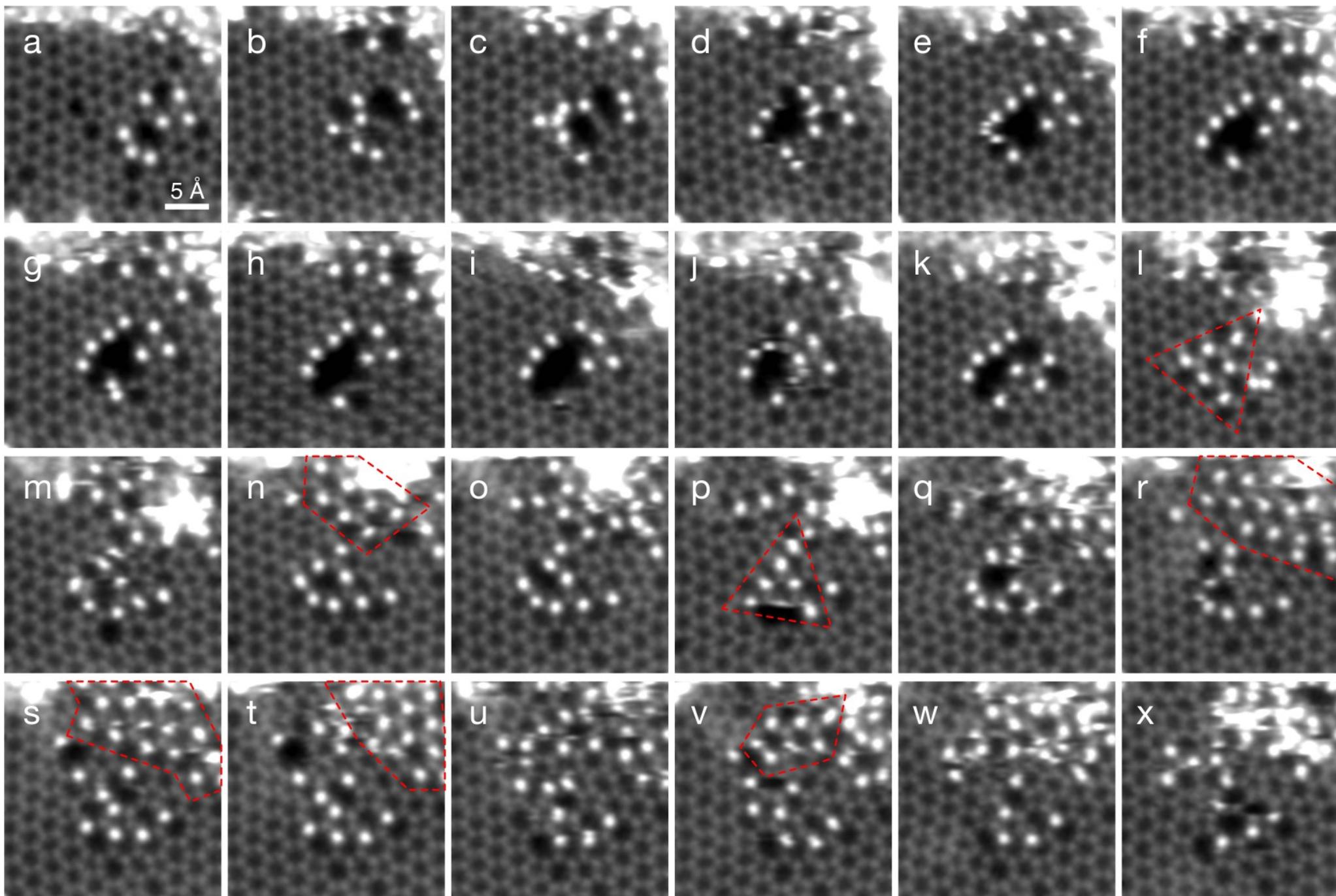
Sample: reduced graphene oxide

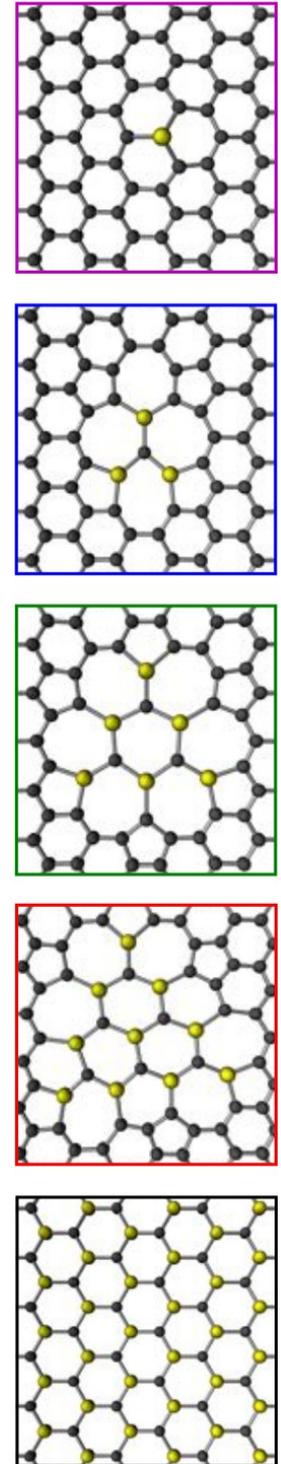
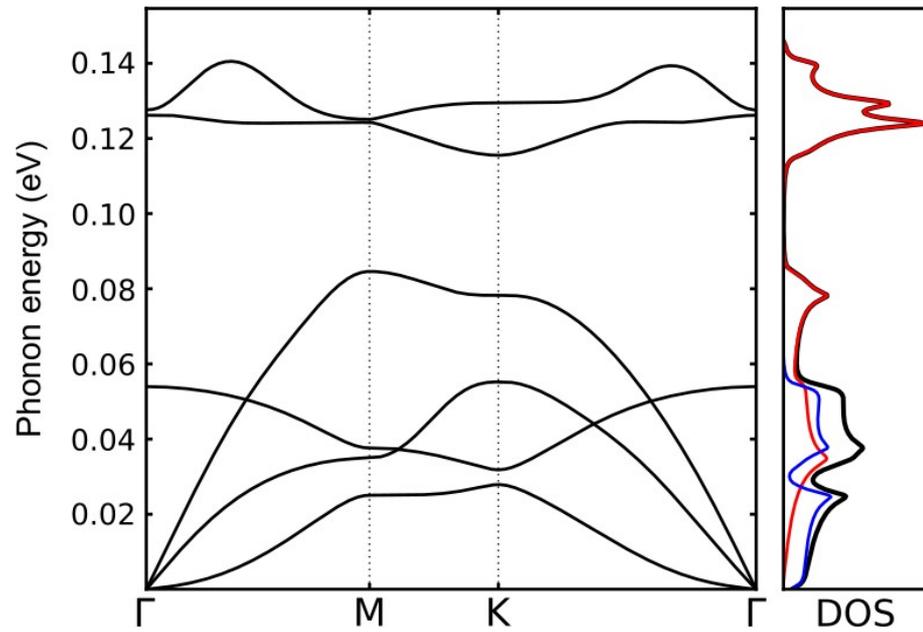
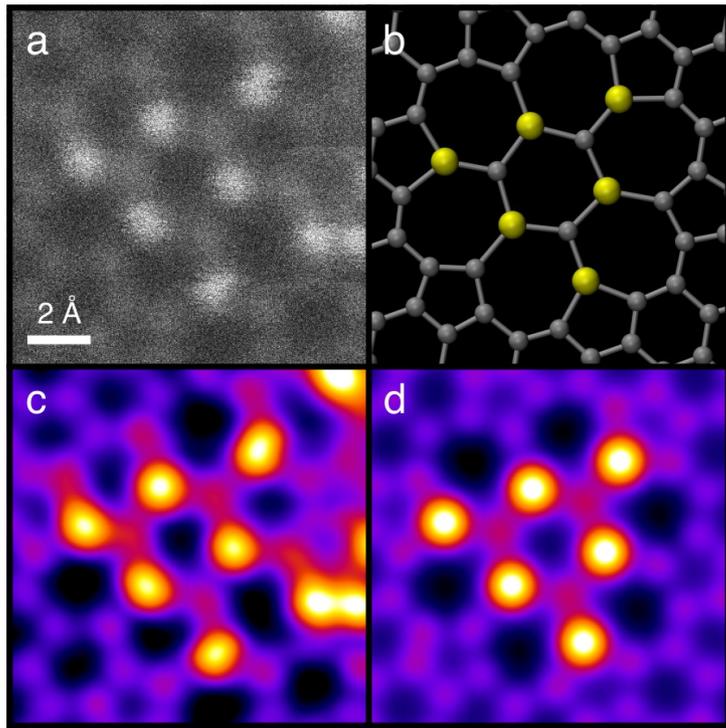
Imaging: Nion UltraSTEM 100 @ 60 kV, ca. 30 pA @ 10^{-9} mbar



@ 60 kV ~ 4-6 eV (Si)
~ 10-13 eV (C)







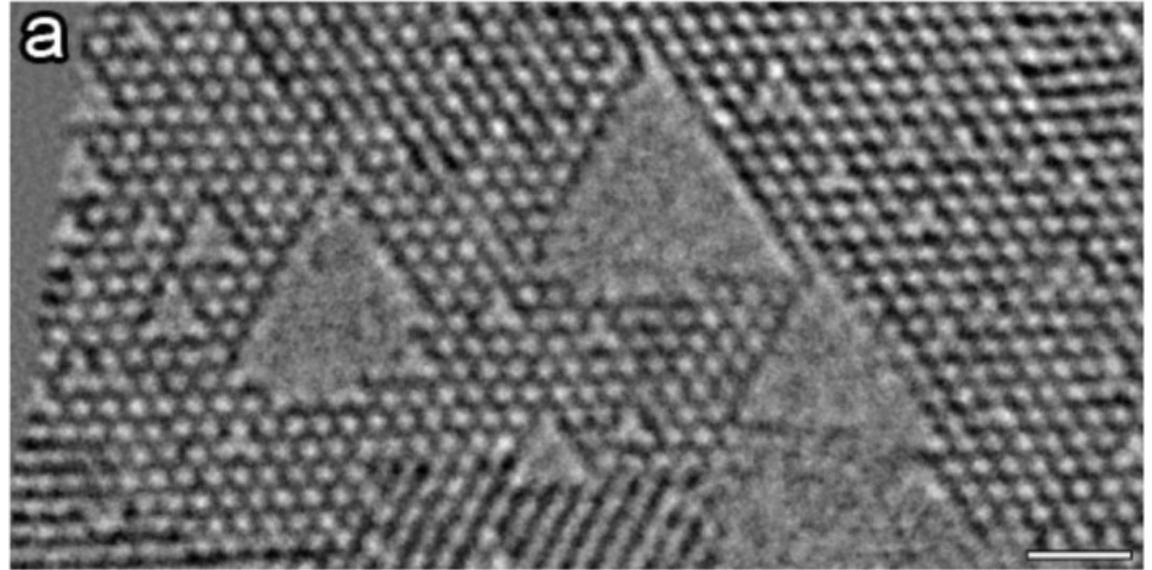
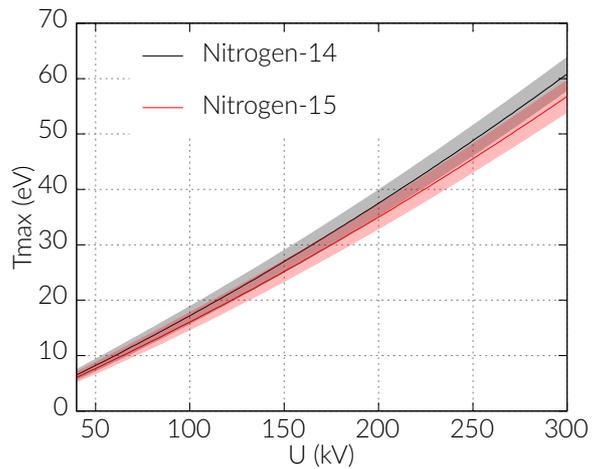
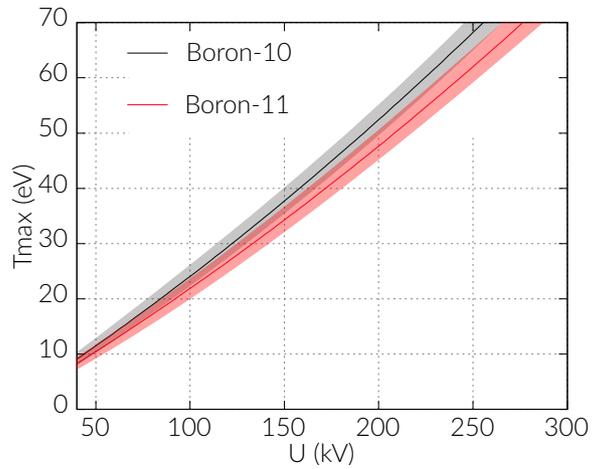
Polytype	2D-SiC	6H (α)	4H	3C (β)
Symmetry	hexagonal	hexagonal	hexagonal	cubic
In-plane lattice constant (\AA)	3.104	3.0810	3.0730	4.3596
Si-C bond length (\AA)	1.792	1.89	1.89	1.89
Bandgap (eV)	2.58	3.05	3.23	2.36
Bulk modulus (GPa)	98.3	220	220	250
Optical phonon energy (meV)	127	102.8	104.2	104.2
C $1s$ – Si $2p$ (eV)	182.19	181.9 ⁴⁵	182.3 ⁴⁶	182.17 ⁴⁷

Knock-On vs. Ionization, or Both?

Electron irradiation of hBN

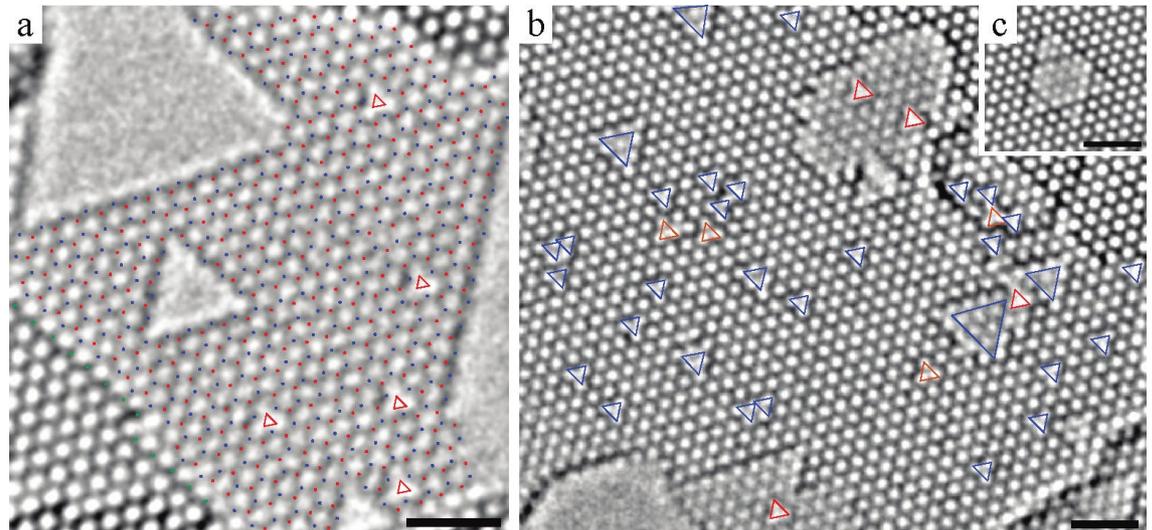
@ 120 kV

5 B Boron 10.01, 11.01	7 N Nitrogen 14.00, 15.00
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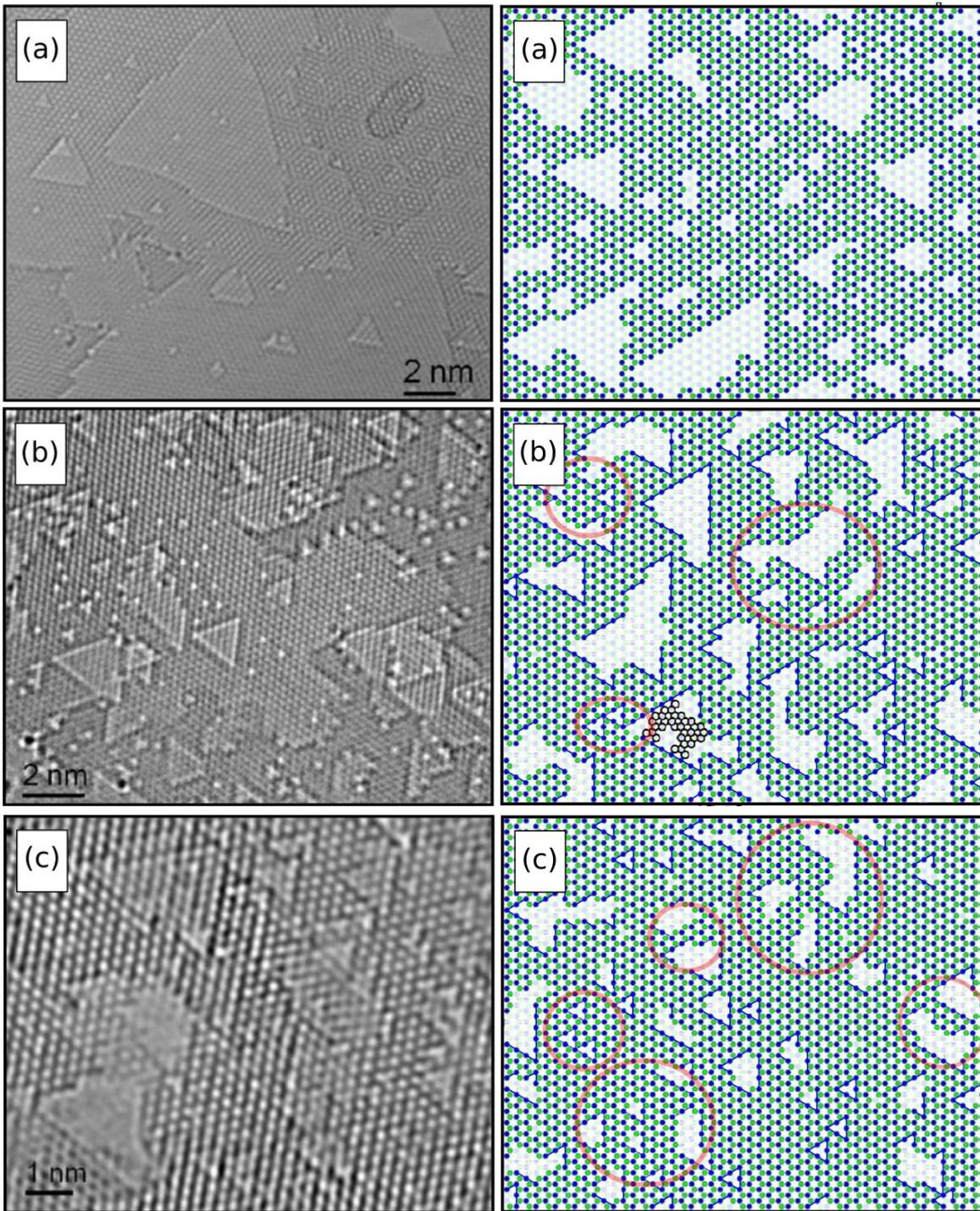


Jin et al., Phys. Rev. Lett. 102, 195505 (2009)

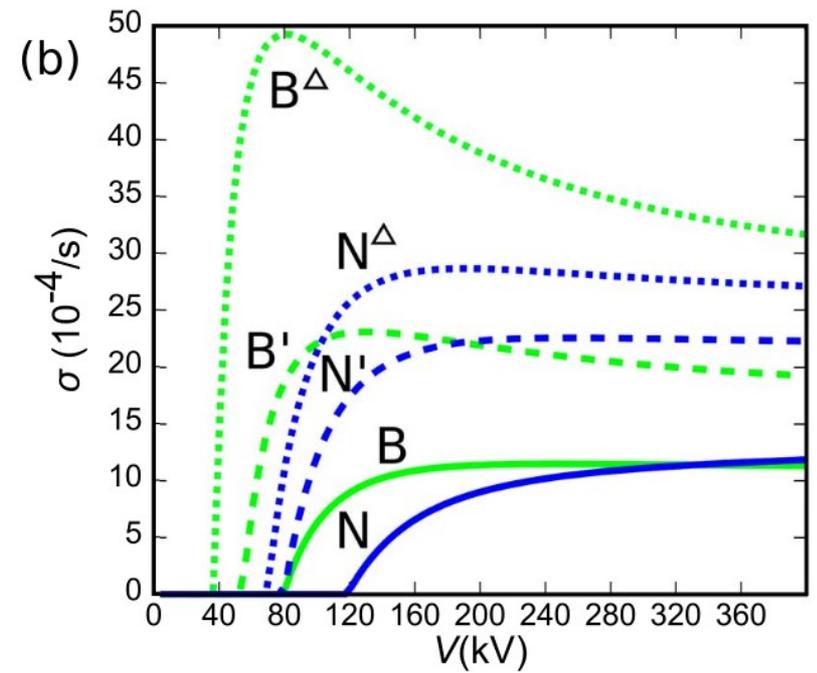
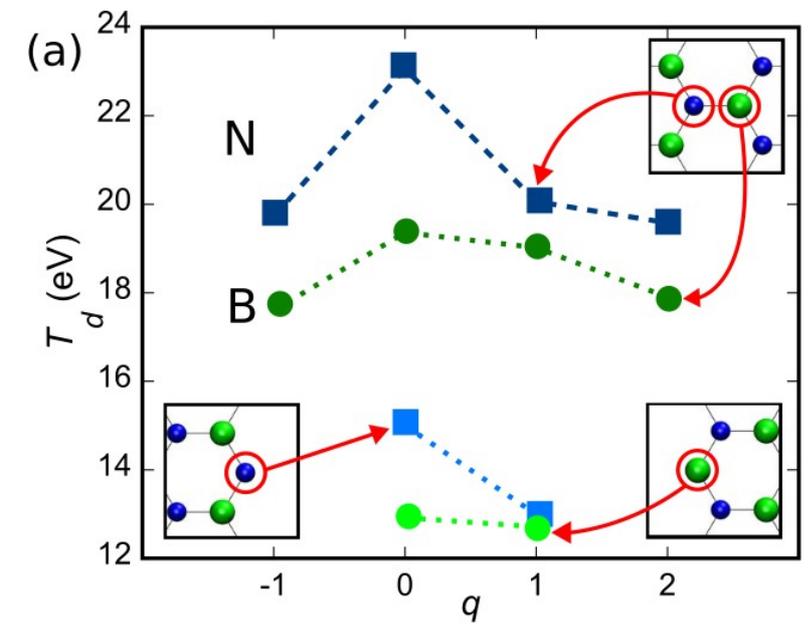
@ 80 kV



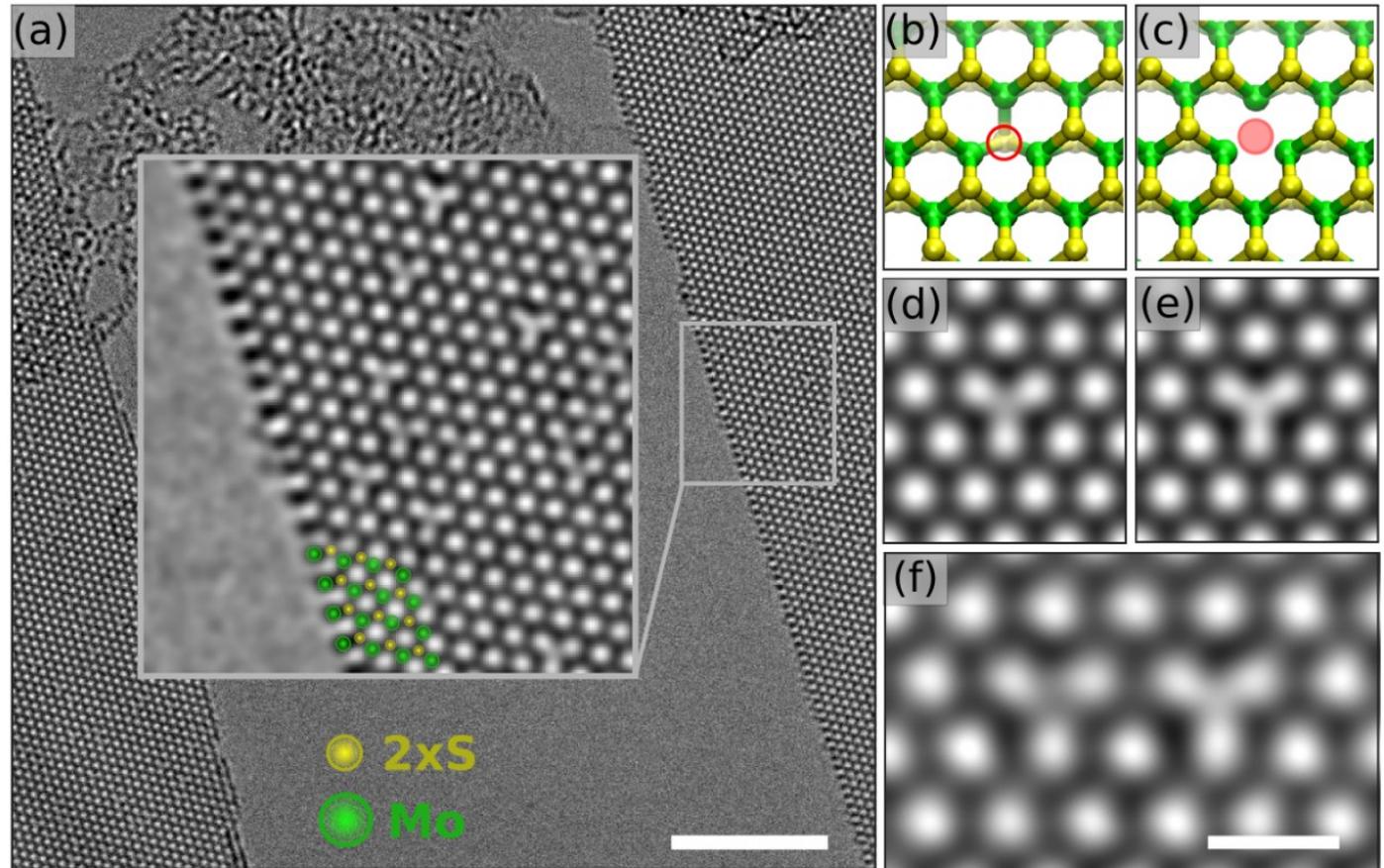
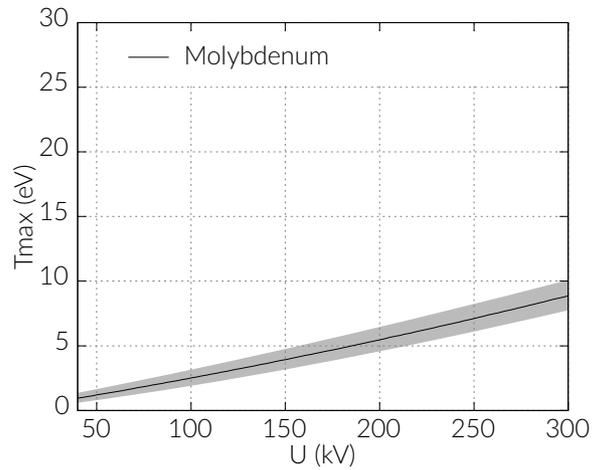
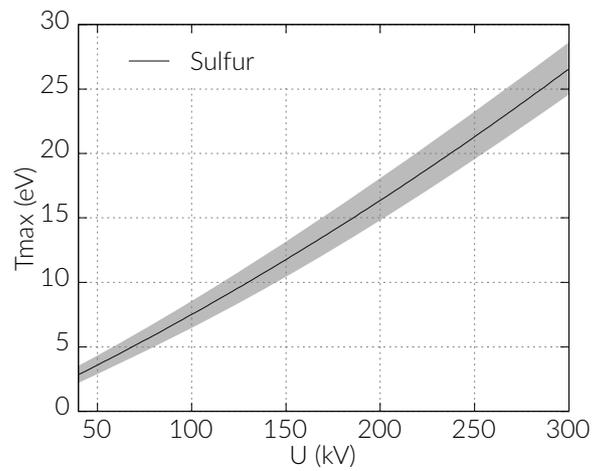
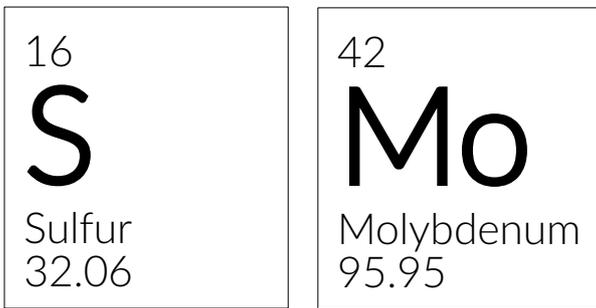
Meyer et al., Nano Lett. 9, 2683 (2009)



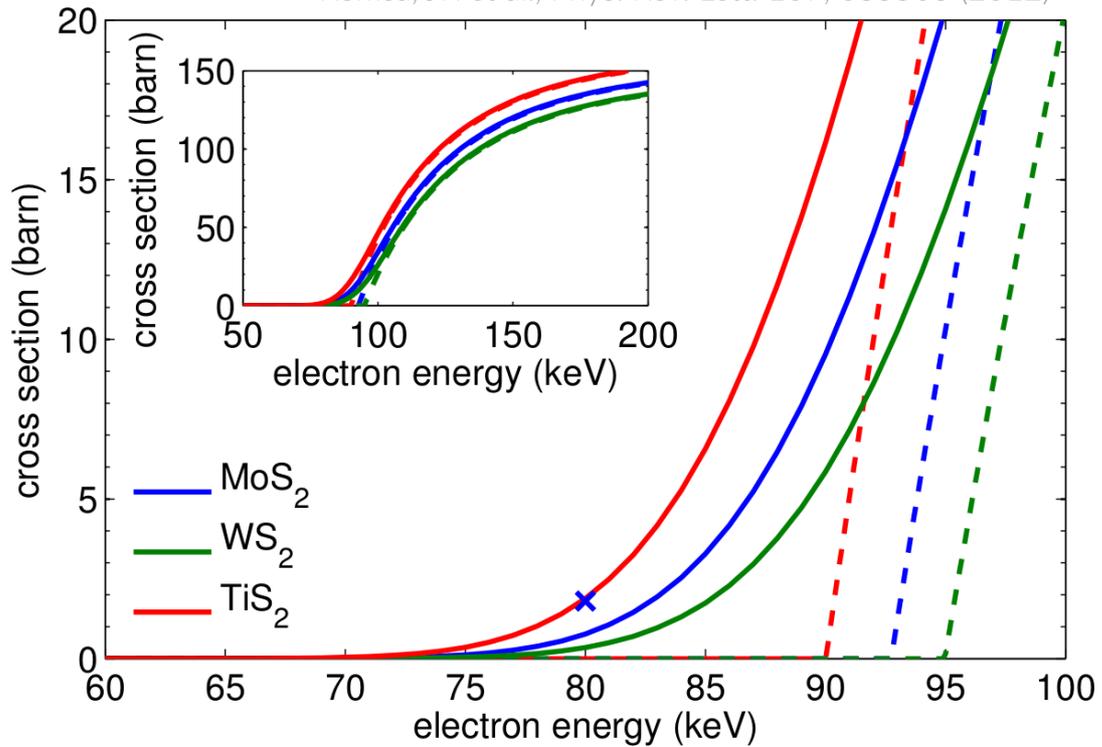
(a) 80 kV (b) 120 kV (c) 200 kV



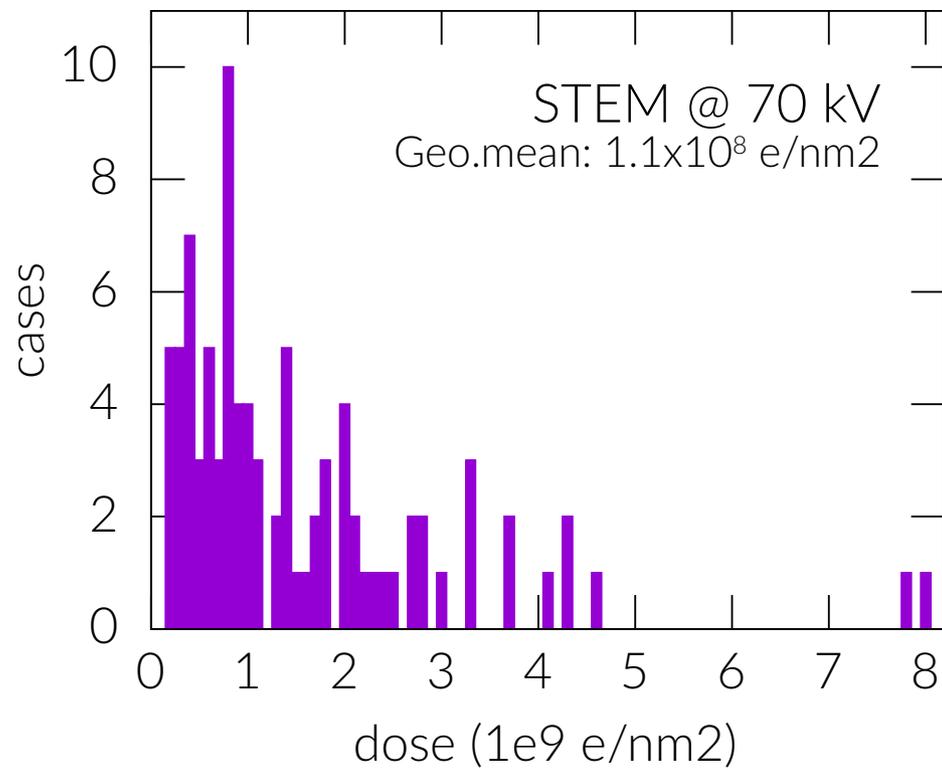
Sulfur Vacancies in MoS₂



Komsa, JK et al., Phys. Rev. Lett. 109, 035503 (2012)



× MoS₂, HRTEM



From Knock-On to Ionization

Heavier TMDs: MoTe₂

42
Mo
Molybdenum
95.95

74
W
Tungsten
183.84

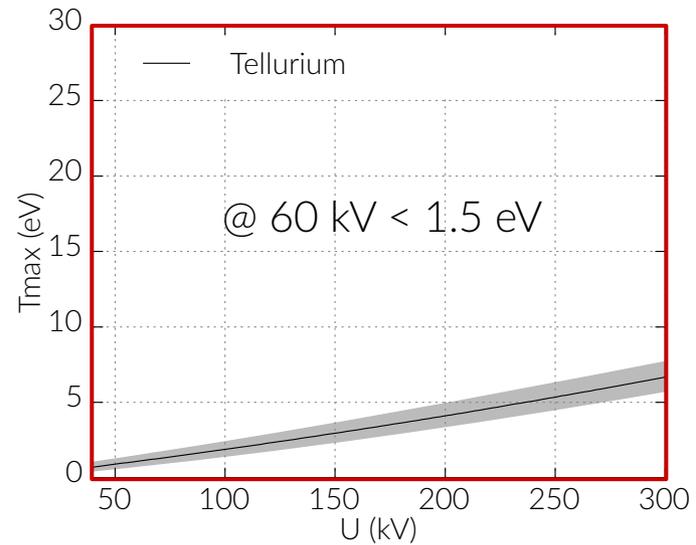
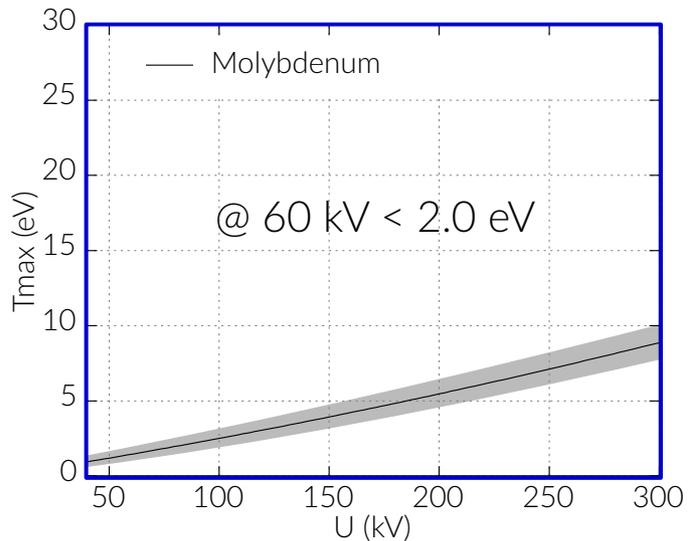
Kuc, Chemical Modelling 11, 1-29 (2014)

1	H	2											13	14	15	16	17	18
	Li	Be											B	C	N	O	F	Ne
	Na	Mg											Al	Si	P	S	Cl	Ar
	K	Ca	3	4	5	6	7	8	9	10	11	12	Ga	Ge	As	Se	Br	Kr
	Rb	Sr	Sc	Ti	V	Cr	Mn	Fe	Co	Ni	Cu	Zn	In	Sn	Sb	Te	I	Xe
	Cs	Ba	Y	Zr	Nb	Mo	Tc	Ru	Rh	Pd	Ag	Cd	Tl	Pb	Bi	Po	At	Rn
	Fr	Ra	Lu	Hf	Ta	W	Re	Os	Ir	Pt	Au	Hg	Pt	Pb	Bi	Po	At	Rn
			Lr	Rf	Db	Sg	Bh	Hs	Mt	Ds	Rg	Cn	Uut	Fl	Uup	Lv	Uus	Uuo
			La	Ce	Pr	Nd	Pm	Sm	Eu	Gd	Tb	Dy	Ho	Er	Tm	Yb		
			Ac	Th	Pa	U	Np	Pu	Am	Cm	Bk	Cf	Es	Fm	Md	No		

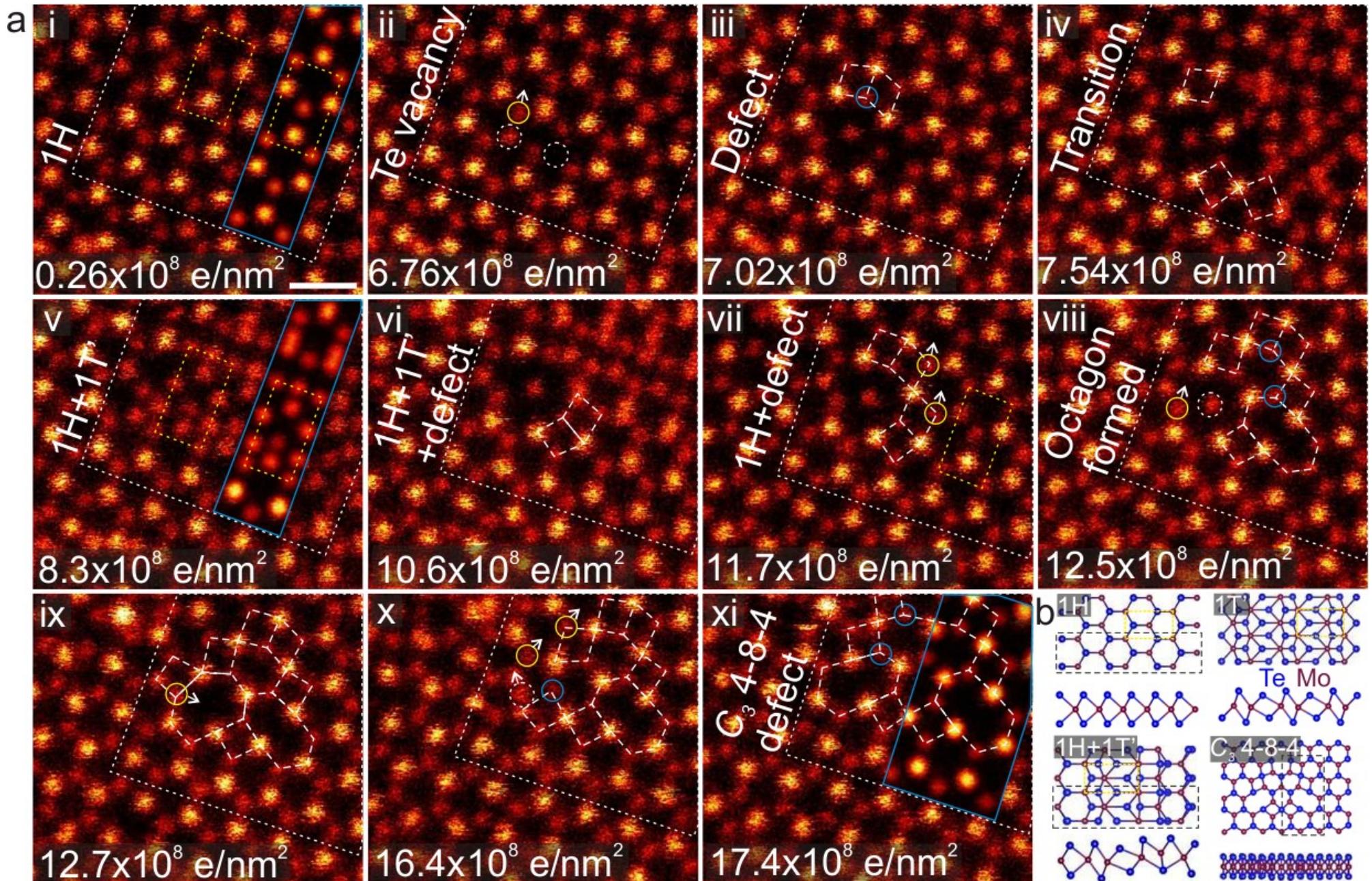
16
S
Sulfur
32.06

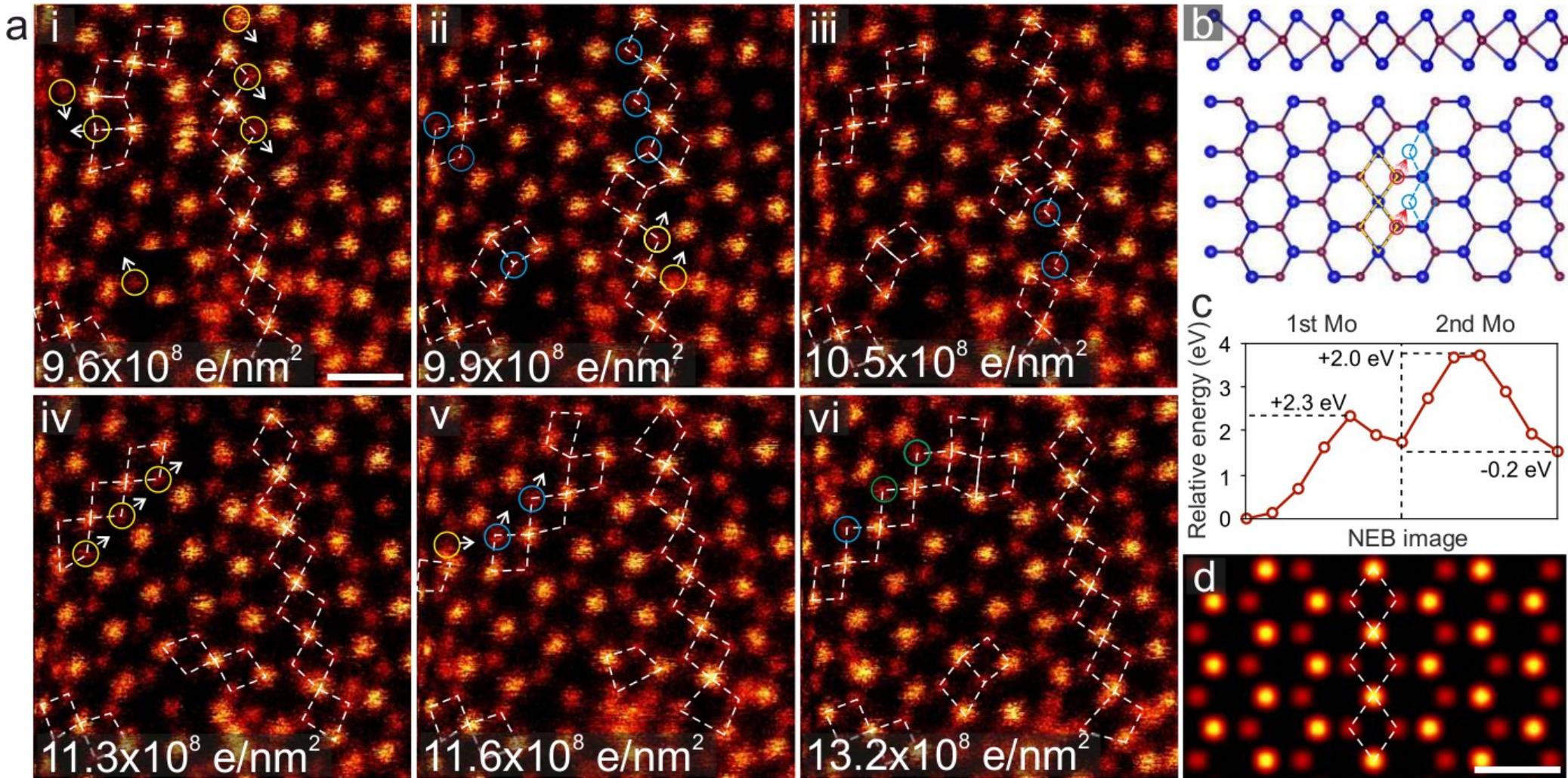
34
Se
Selenium
78.971

52
Te
Tellurium
127.60

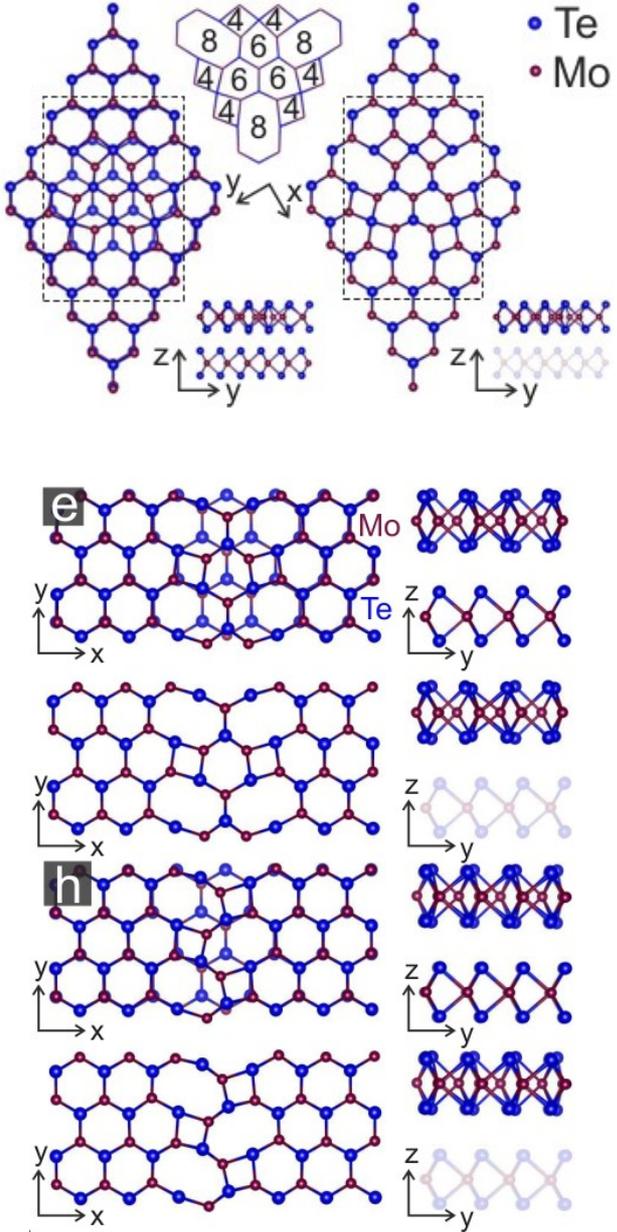
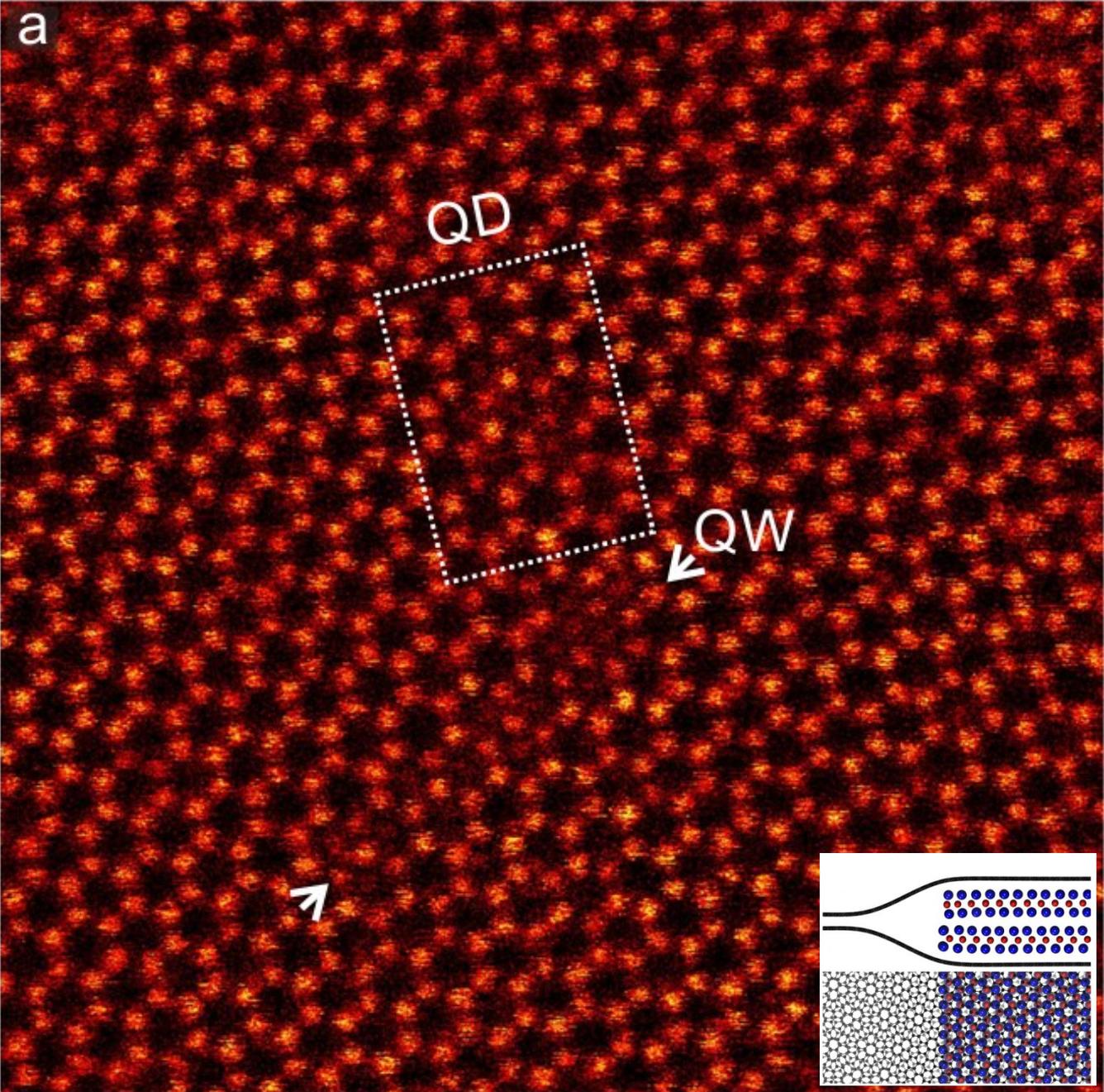


Non-knock-on dynamics





Intrinsic defects

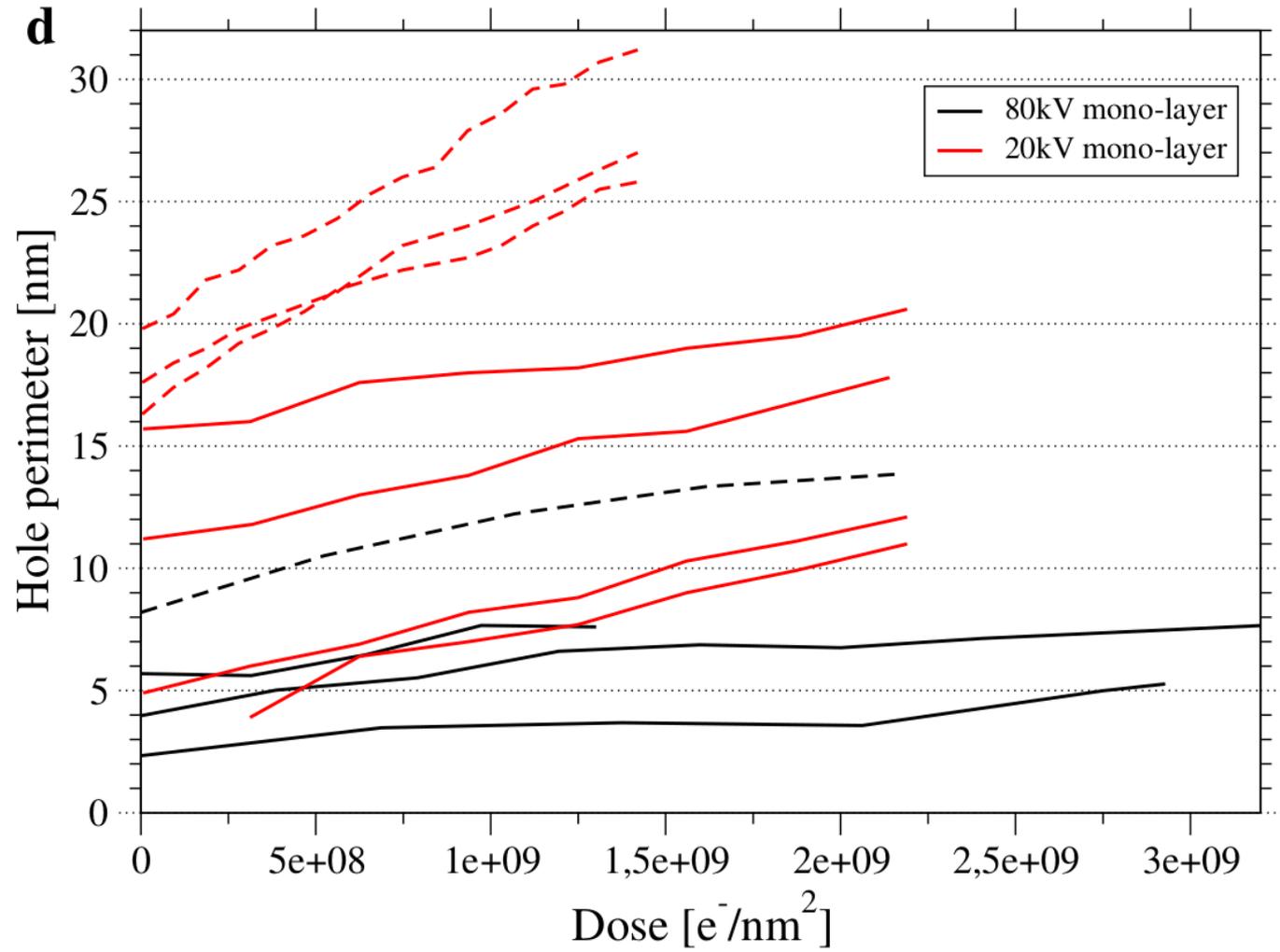
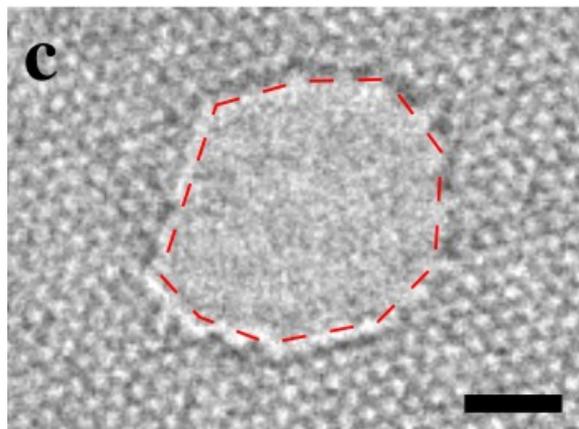
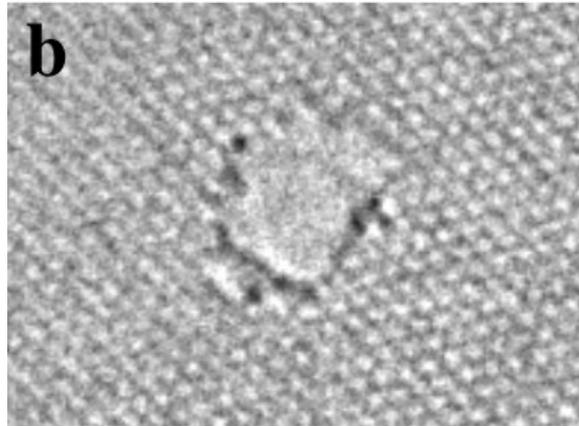
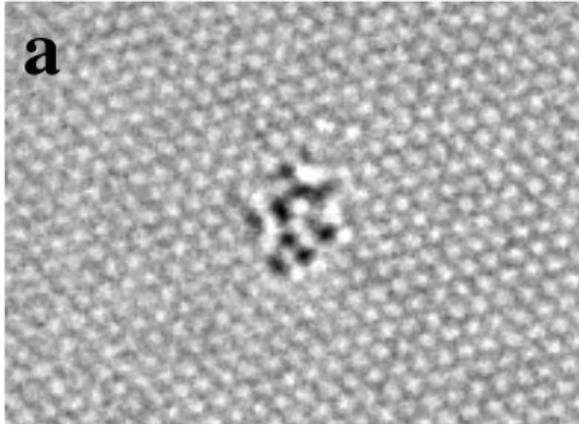


TMD-protection through sandwiching:
Algara-Siller et al., Appl. Phys. Lett. 103, 203107 (2013)

Elibol, ... , JK, Chem. Mater. 30, 1230 (2018)

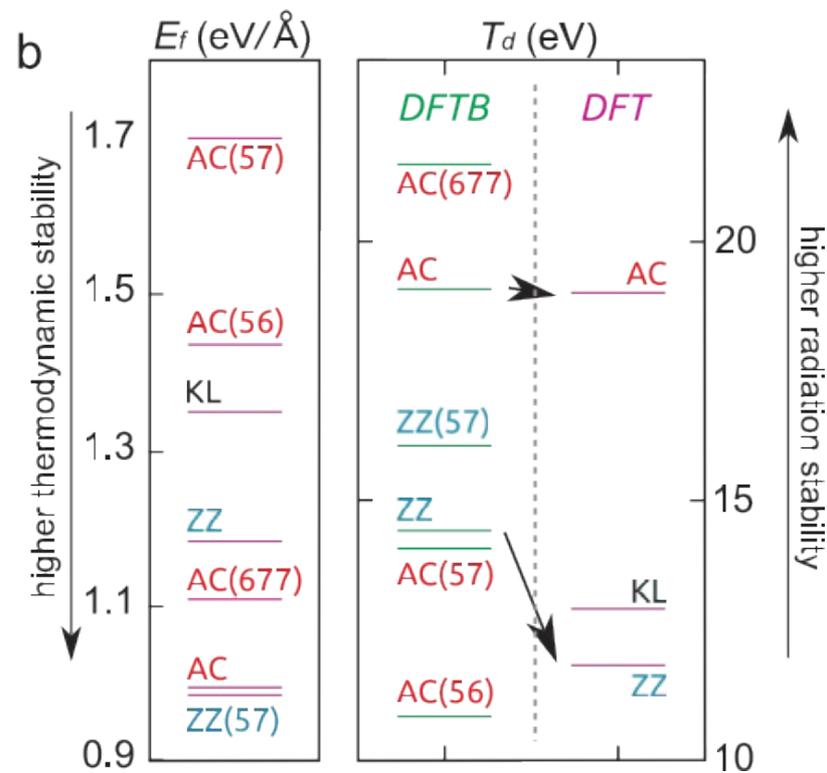
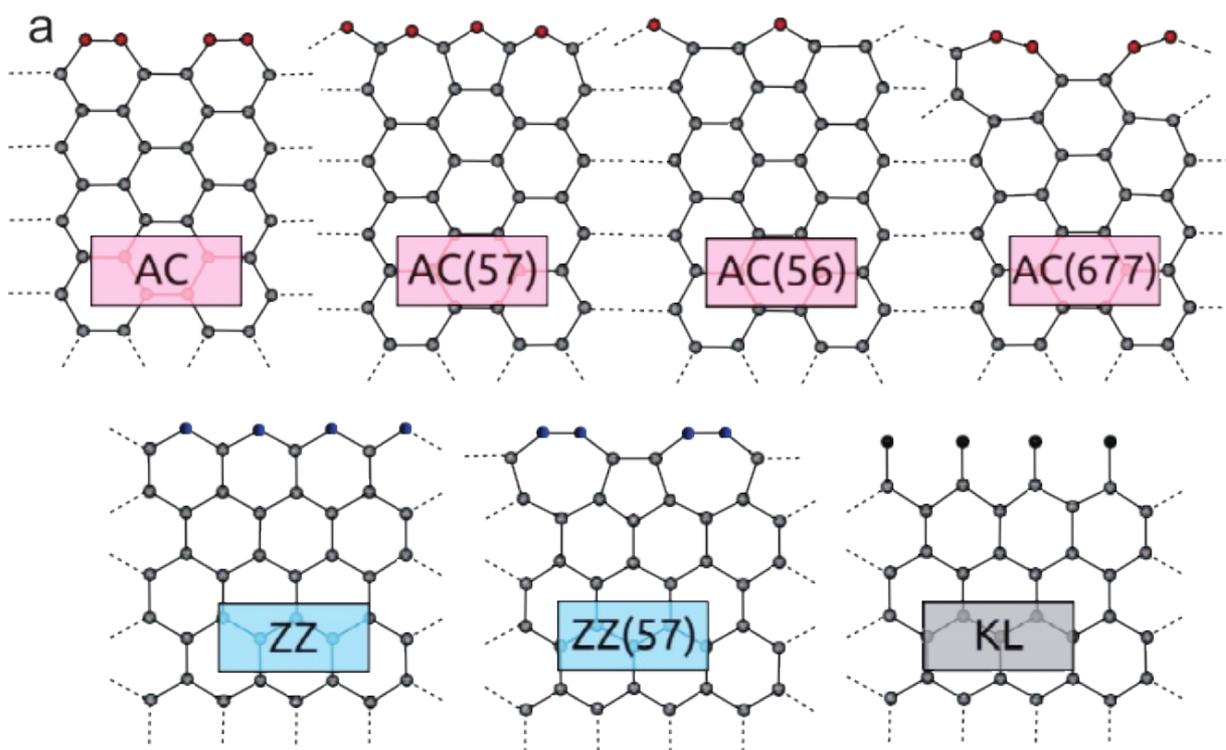
Graphene Edges under the Electron Beam

Typical Results in a HRTEM: Growing Holes

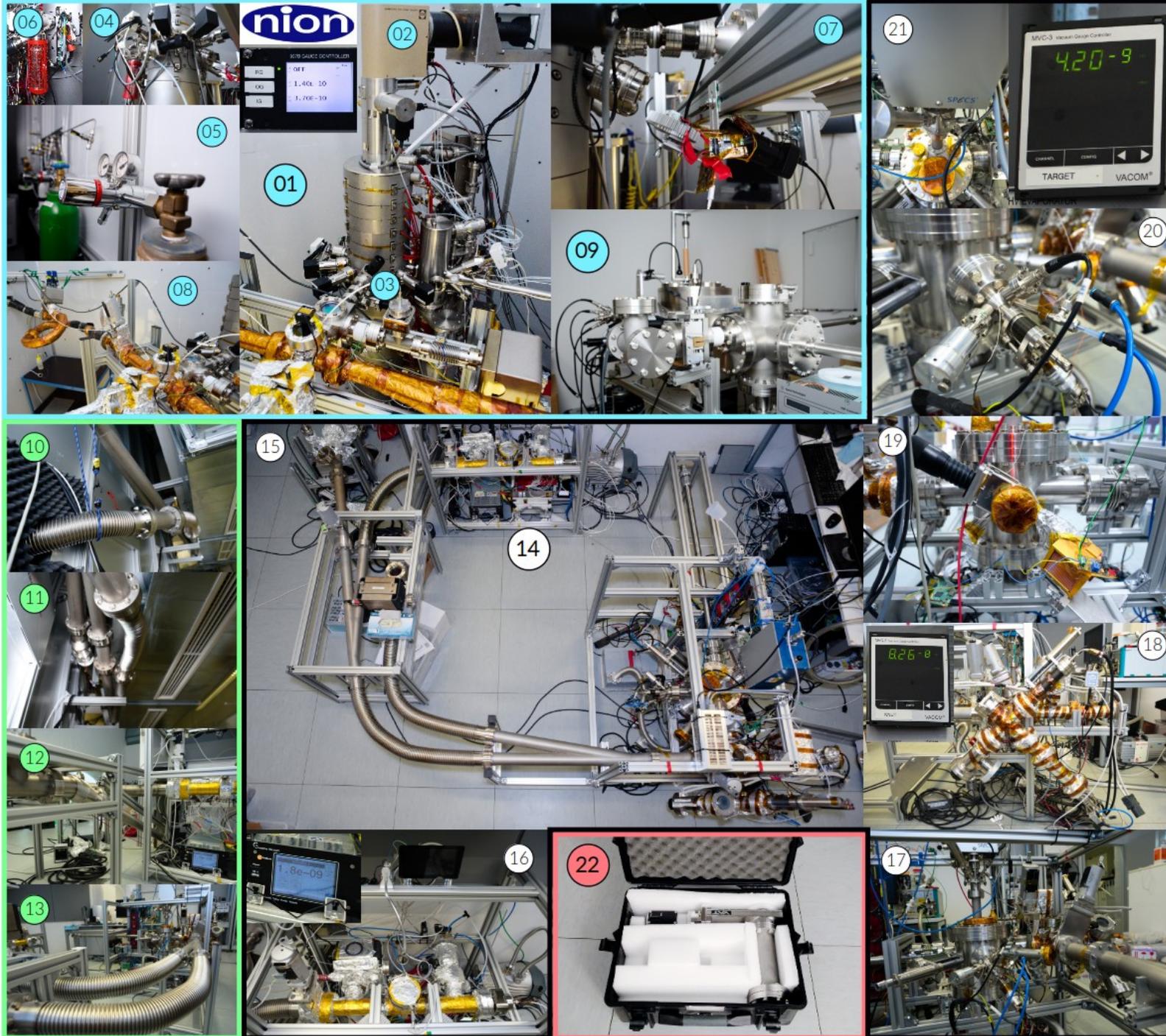


What Should We Expect?

Knock-on damage at various edges



Experimental setup in Vienna



1st FLOOR

- 01 - Nion UltraSTEM 100
- 02 - EELS
Gatan PEELS 666 spectrometer
Andor iXon 897 EMCCD
- 03 - Customized objective area
- 04 - Leak valve
- 05 - Gas distribution line
- 06 - Non-evaporating getter (NEG)
Pressure @ sample: 1.4e-10 mbar
- 07 - 6W diode laser (445 nm)
- 08 - Custom UHV sample entry
- 09 - Getec self-sensing AFSEM
(installation to finish in 2018)

TRANSFER

- 10 Line out from microscope room
- 11 To AFM and 2nd floor
- 12 Entry to 2nd floor
- 13 To loadlock and manipulation

2nd FLOOR

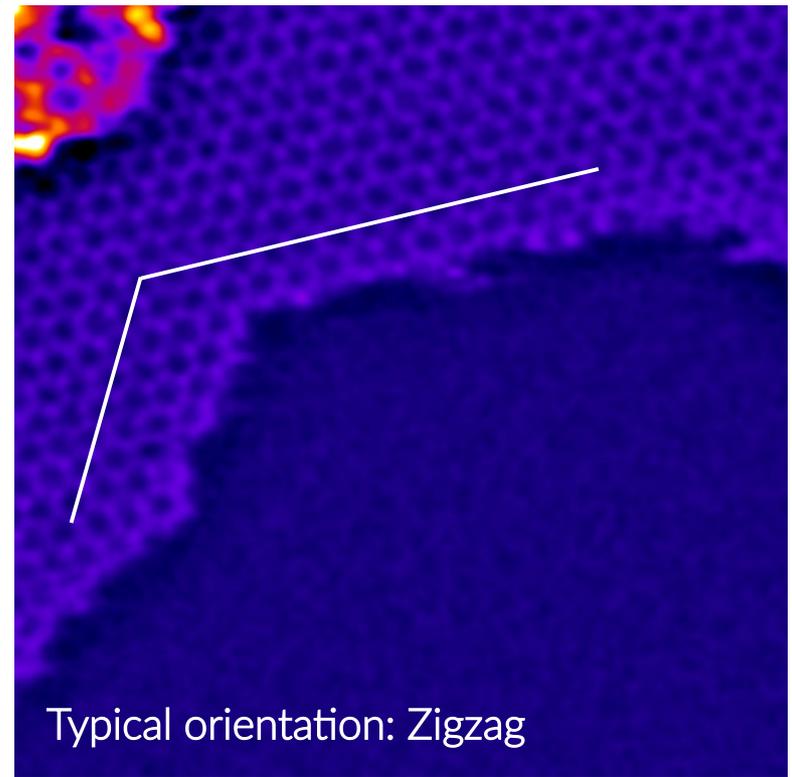
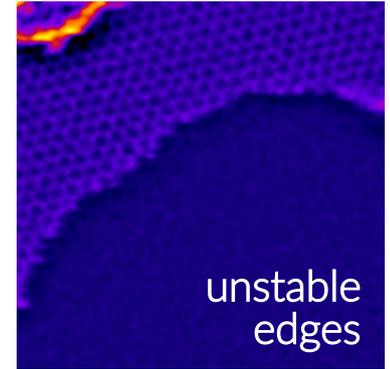
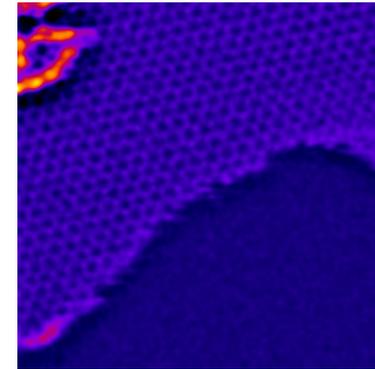
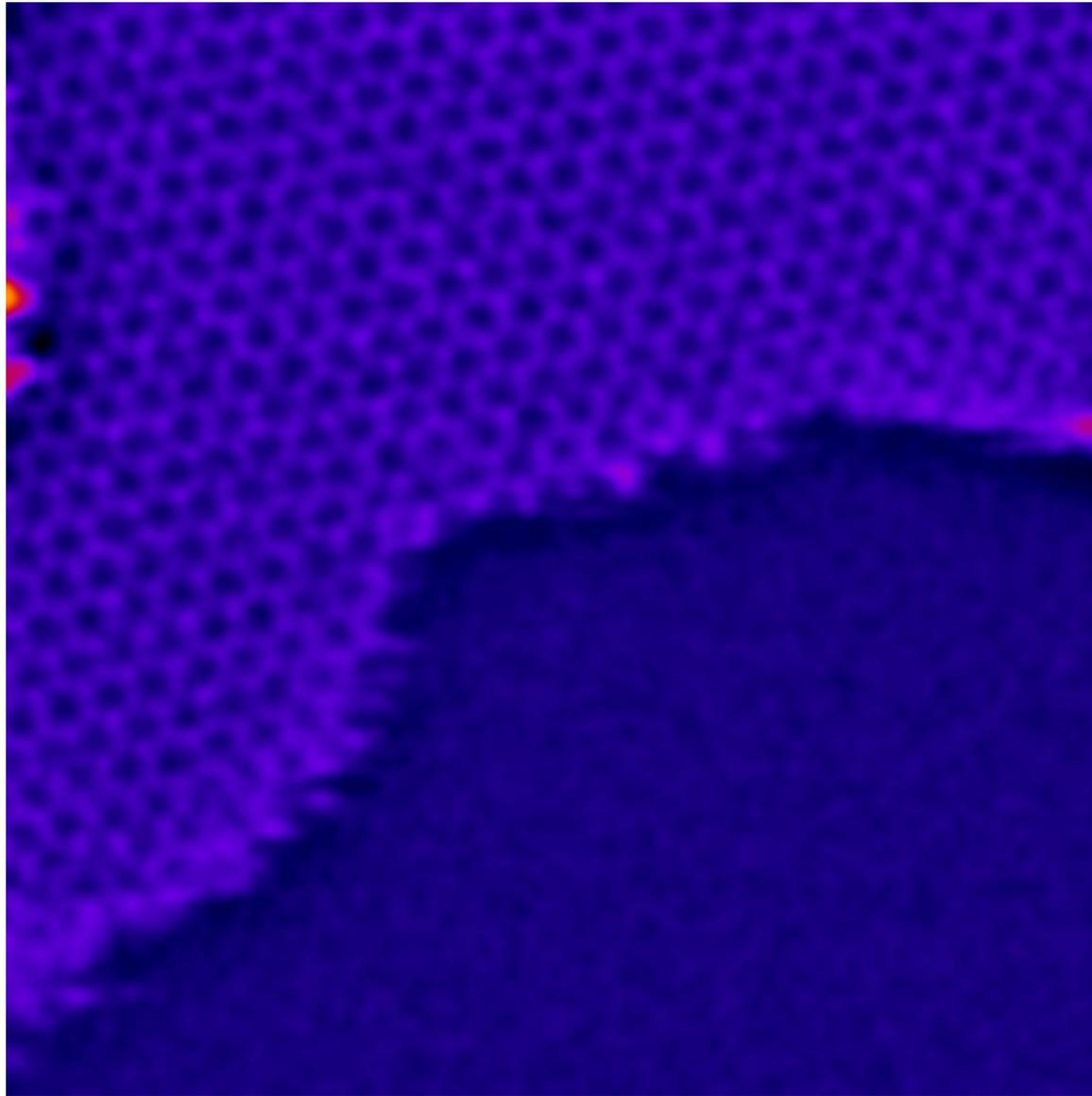
- 14 2nd floor setup
- 15 Storage for samples
- 16 Load lock and bake (150°C)
- 17 Manipulation system
- 18 Knudsen evaporation cell
- 19 Ion beam entry & 6W diode laser
(ion beam to arrive in 2018)
- 20 e-beam evaporator
- 21 Plasma ion source

SUITCASE

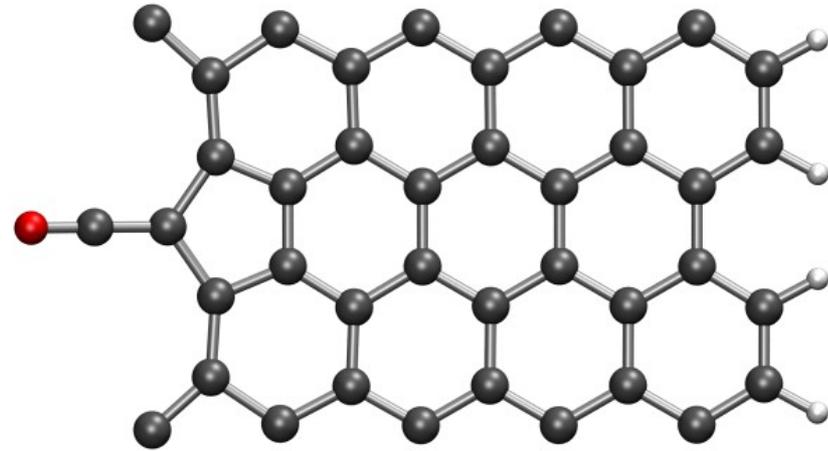
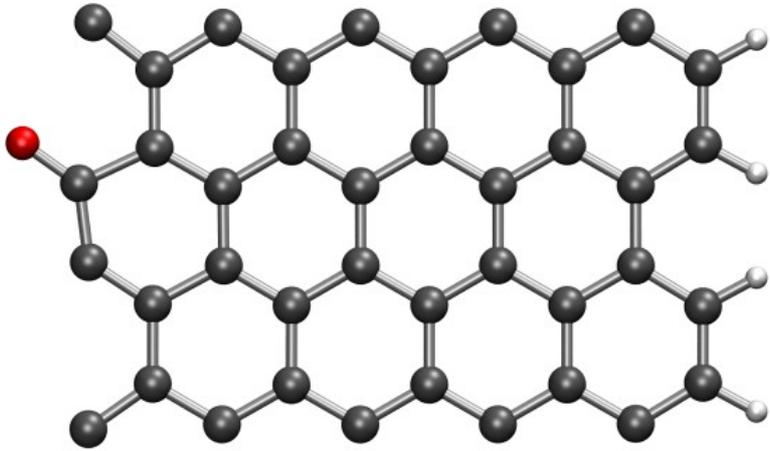
- 22 Ar+ suitcase (sample transfer)

... in a STEM at 10^{-7} to 10^{-6} mbar (O_2)

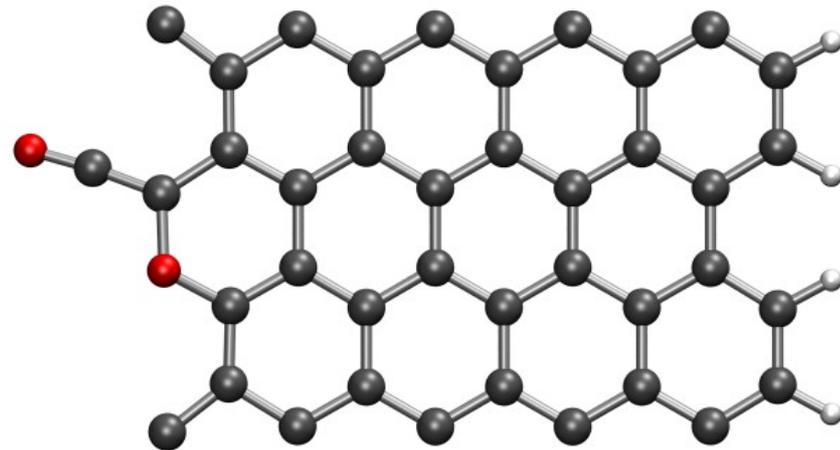
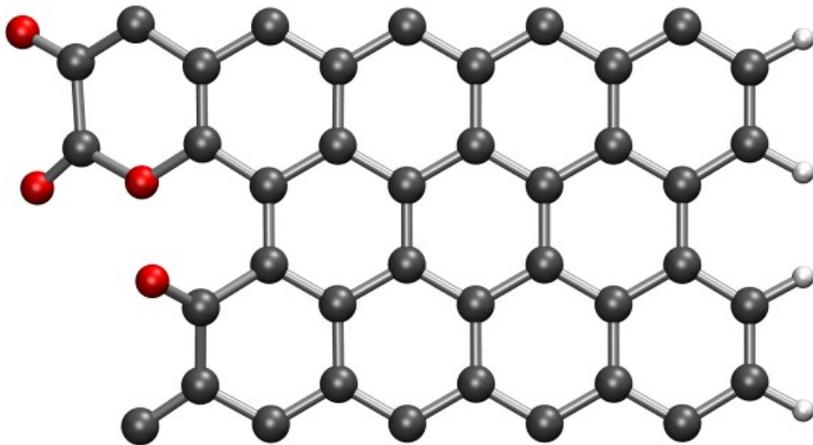
STEM imaging at 60 kV



Near-barrierless reconstruction



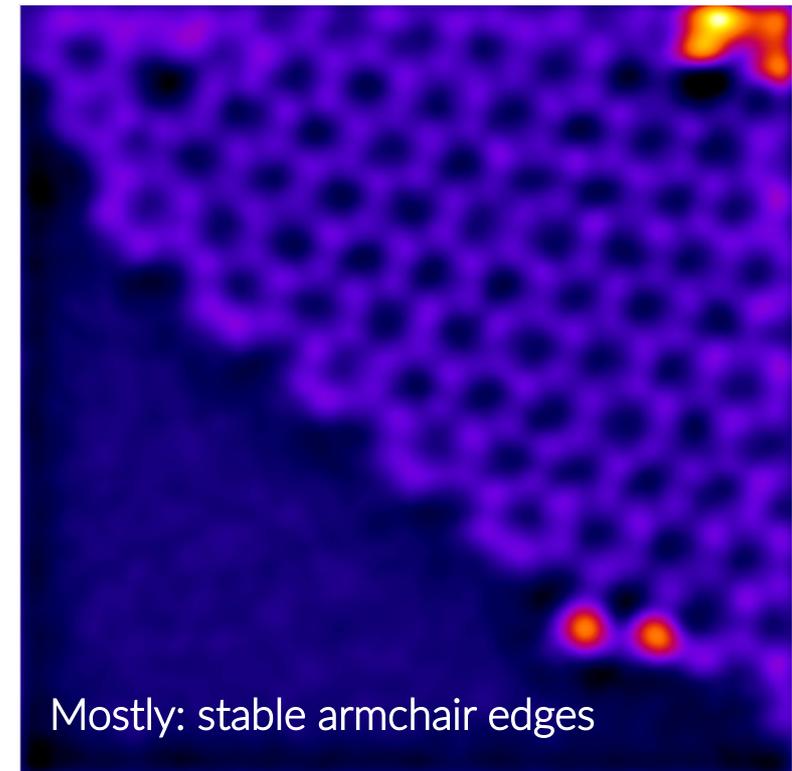
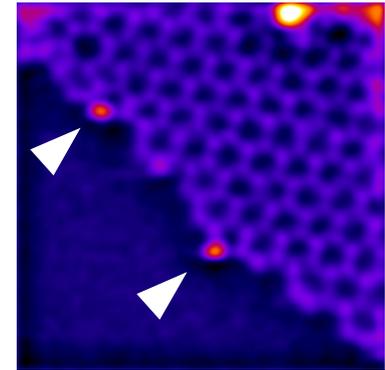
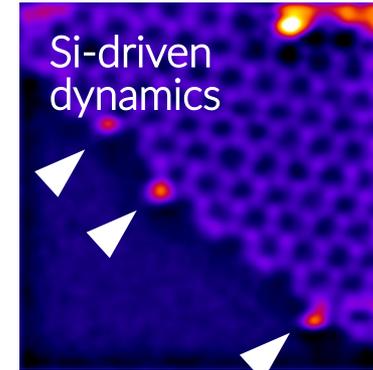
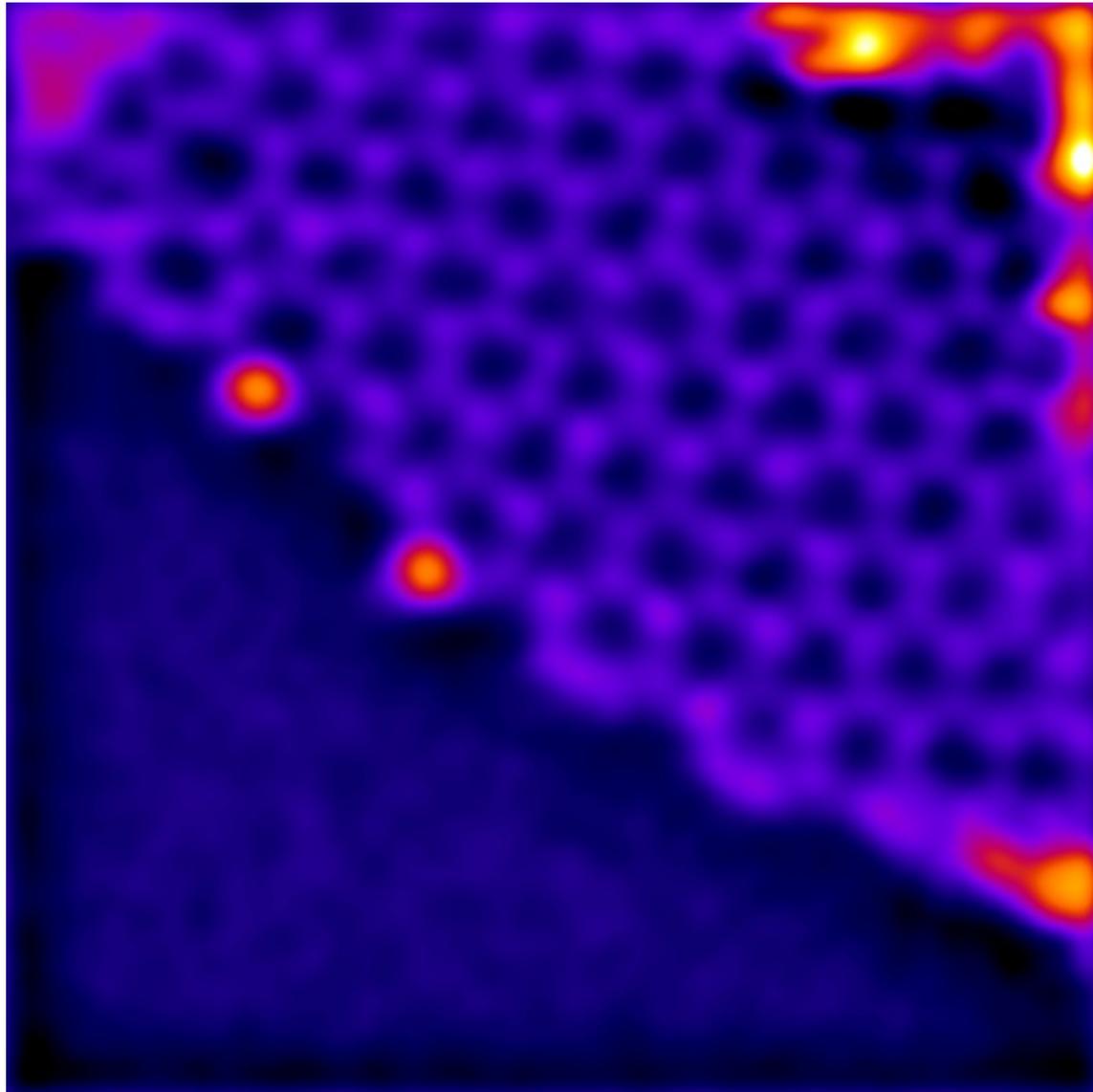
Absorbing more O atoms on C–C bridges...



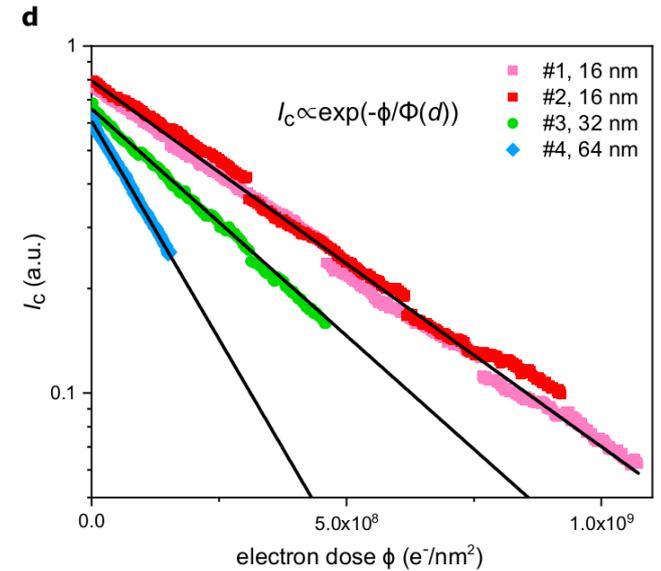
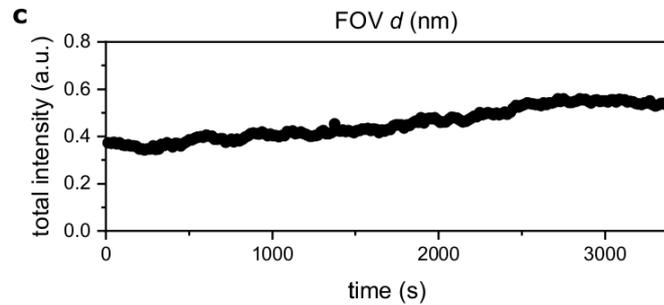
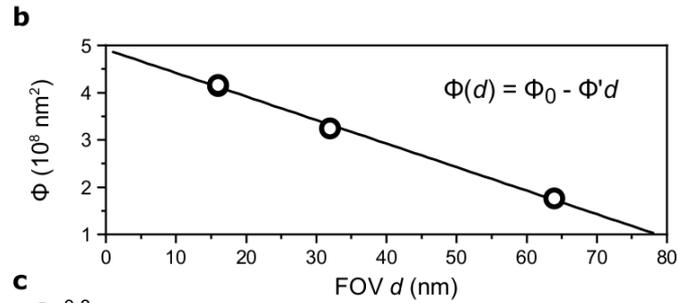
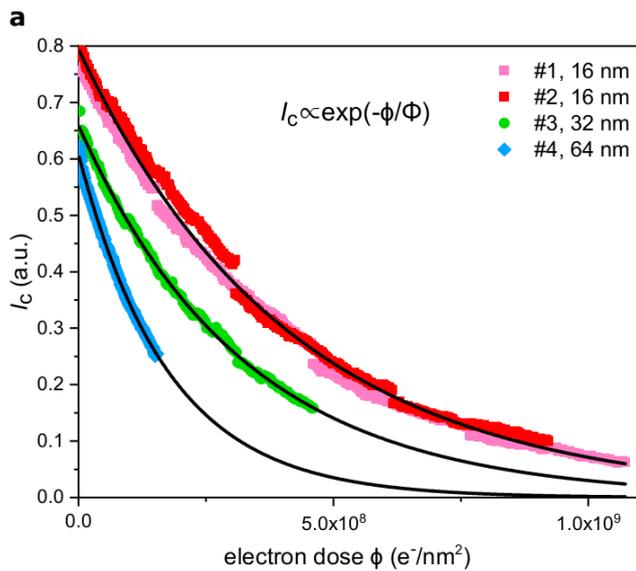
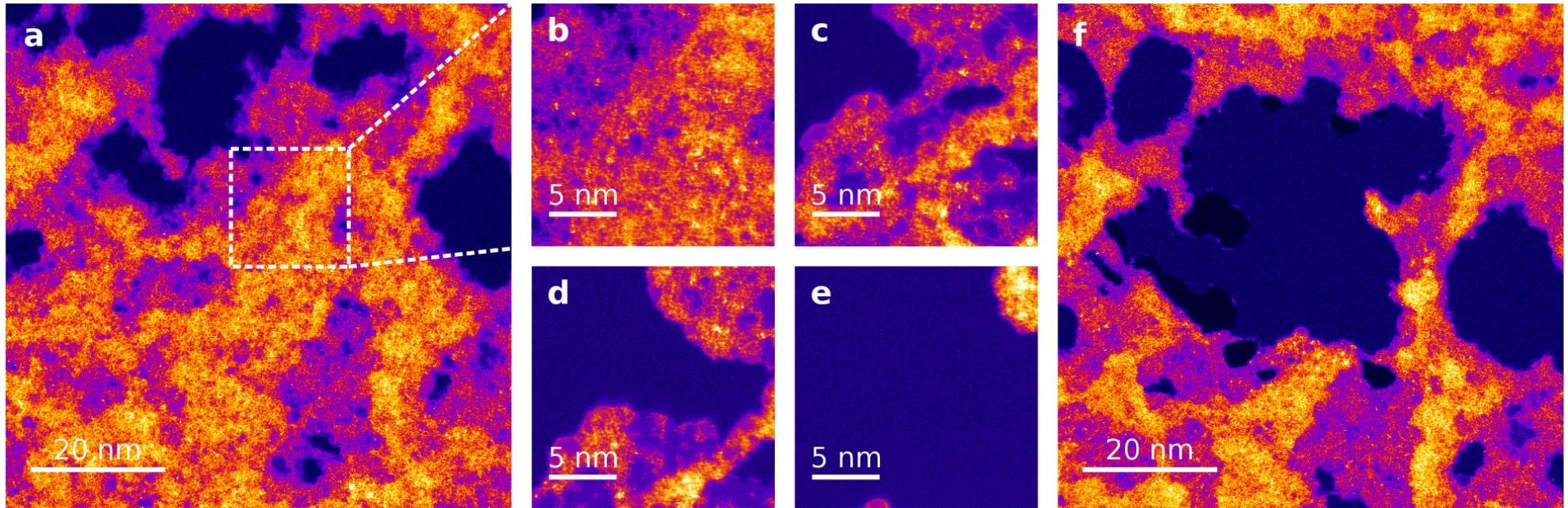
...leads to the edge unraveling with no barrier

How About in UHV?

STEM imaging at 60 kV and ca. 2×10^{-10} mbar



Etching-Induced Cleaning @ 10^{-7} mbar (Air)

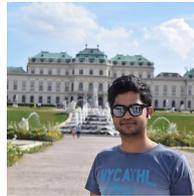


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